

Global United Technology Services Co., Ltd.

Report No.: GTS201708000110F02

FCC Report (LTE)

Connected Holdings LLC Applicant:

4740 Von Karman Avenue, Suite 120, Newport Beach, **Address of Applicant:**

California 92660, United States

Manufacturer: Gemtek Technology Co., Ltd.

Address of No. 15-1 Zhonghua Road, Hsinchu Industrial Park, Hukou,

Hsinchu, Taiwan, 30352 Manufacturer:

Equipment Under Test (EUT)

Product Name: GPS Tracker

Model No.: AR-4LH

Marketing Name: Arrow-L

FCC ID: 2AEB4ALT01

FCC CFR Title 47 Part 2: 2017 **Applicable standards:**

> FCC CFR Title 47 Part 24: 2017 FCC CFR Title 47 Part 27: 2017

Date of sample receipt: July 03, 2017

Date of Test: July 03-07, 2017

Date of report issued: July 07, 2017

PASS * Test Result:

In the configuration tested, the EUT complied with the standards specified above.

Authorized Signature:

Robinson Laboratory Manager

This results shown in this test report refer only to the sample(s) tested, this test report cannot be reproduced, except in full, without prior written permission of the company. The report would be invalid without specific stamp of test institute and the signatures of compiler and approver.



1 Version

Version No.	Date	Description
00	July 07, 2017	Original

Prepared By:	Joseph Cly	Date:	July 07, 2017
	Project Engineer	_	
Check By:	Andy wa	Date:	July 07, 2017
	Reviewer (



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3 Test Summary

Test Item	Section in CFR 47	Result	
DE Eveneure (CAD)	Part 1.1307		
RF Exposure (SAR)	Part 2.1093	Pass*	
	Part 2.1046		
RF Output Power	Part 24.232 (c)	Pass	
	Part 27.50(c)(10)/(d)(4)		
Modulation Characteristics	Part 2.1047	N/A	
	Part 2.1049		
99% & -26 dB Occupied Bandwidth	Part 24.238	Pass	
	Part 27.53(h)/(g)		
	Part 2.1051		
Spurious Emissions at Antenna Terminal	Part 24.238 (a)	Pass	
	Part 27.53(h)/(g)		
	Part 2.1053		
Field Strength of Spurious Radiation	Part 24.238 (a)	Pass	
	Part 27.53(h)/(g)		
Out of hand emission, Rand Edge	Part 24.238 (a)	Door	
Out of band emission, Band Edge	Part 27.53(h)/(g)	Pass	
Frequency stability vs. temperature	Part 2.1055(a)(1)(b)	Pass	
Frequency stability vs. voltage	Part 2.1055(d)(1)(2)	Pass	

Pass: The EUT complies with the essential requirements in the standard.

N/A: Not applicable.



4 General Information

4.1 General Description of EUT

Product Name:	GPS Tracker
Model No.:	AR-4LH
Hardware Version:	P1.1
Software Version:	01.01.00.999
Support Networks:	LTE
Support Bands:	LTE Band 2, LTE Band 4, LTE Band 12
Channel Bandwidth:	LTE Band 2: 5MHz; 10MHz; 15MHz; 20MHz
	LTE Band 4: 5MHz; 10MHz; 15MHz; 20MHz
	LTE Band 12: 5MHz; 10MHz
TX Frequency:	LTE Band 2: 1850.70MHz-1909.30MHz
	LTE Band 4: 1710.70MHz-1754.30MHz
	LTE Band 12: 698.70MHz-715.30MHz
Modulation type:	LTE Band 2/4/12: QPSK, 16QAM
Antenna type:	Integral antenna
Antenna gain:	2.5dBi(Band 2), 2.5dBi(Band 4), 0.4dBi(Band 12)
Power supply:	Battery: DC3.7V, 296mWh Input: DC12V



4.2 Related Submittal(s) / Grant (s)

This submittal(s) (test report) is filing to comply with Section Part 27 of the FCC CFR 47 Rules.

4.3 Test Methodology

Both conducted and radiated testing were performed according to the procedures document on TIA/EIA 603 and FCC CFR 47.1046, 2.1047, 2.1049, 2.1051, 2.1053, 2.1055 and 2.1057

4.4 Test Facility

The test facility is recognized, certified, or accredited by the following organizations:

• FCC —Registration No.: 600491

Global United Technology Services Co., Ltd., Shenzhen EMC Laboratory has been registered and fully described in a report filed with the (FCC) Federal Communications Commission. The acceptance letter from the FCC is maintained in files. Registration 600491, June 22, 2016.

• Industry Canada (IC) —Registration No.: 9079A-2

The 3m Semi-anechoic chamber of Global United Technology Services Co., Ltd. has been registered by Certification and Engineering Bureau of Industry Canada for radio equipment testing with Registration No.: 9079A-2, August 15, 2016.

4.5 Test Location

All tests were performed at:

Global United Technology Services Co., Ltd.

Address: No. 301-309, 3/F., Jinyuan Business Building, No.2, Laodong Industrial Zone, Xixiang Road, Baoan District, Shenzhen, Guangdong, China 518102

Tel: 0755-27798480 Fax: 0755-27798960



5 Test Instruments list

Rad	Radiated Emission:								
Item	Test Equipment	Manufacturer	Model No.	Inventory No.	Cal.Date (mm-dd-yy)	Cal.Due date (mm-dd-yy)			
1	3m Semi- Anechoic Chamber	ZhongYu Electron	9.0(L)*6.0(W)* 6.0(H)	GTS250	July. 03 2015	July. 02 2020			
2	Control Room	ZhongYu Electron	6.2(L)*2.5(W)* 2.4(H)	GTS251	N/A	N/A			
3	Spectrum Analyzer	Agilent	E4440A	GTS533	Jun. 29 2017	Jun. 28 2018			
4	EMI Test Receiver	Rohde & Schwarz	ESU26	GTS203	Jun. 29 2017	Jun. 28 2018			
5	BiConiLog Antenna	SCHWARZBECK MESS-ELEKTRONIK	VULB9163	GTS214	Jun. 29 2017	Jun. 28 2018			
6	Double -ridged waveguide horn	SCHWARZBECK MESS-ELEKTRONIK	9120D-829	GTS208	Jun. 29 2017	Jun. 28 2018			
7	Horn Antenna	ETS-LINDGREN	3160	GTS217	Mar. 25 2017	Mar. 24 2018			
8	EMI Test Software	AUDIX	E3	N/A	N/A	N/A			
9	Coaxial Cable	GTS	N/A	GTS213	Mar. 25 2017	Mar. 24 2018			
10	Coaxial Cable	GTS	N/A	GTS211	Mar. 25 2017	Mar. 24 2018			
11	Coaxial cable	GTS	N/A	GTS210	Mar. 25 2017	Mar. 24 2018			
12	Coaxial Cable	GTS	N/A	GTS212	Mar. 25 2017	Mar. 24 2018			
13	Amplifier(100kHz-3GHz)	HP	8347A	GTS204	Jun. 29 2017	Jun. 28 2018			
14	Amplifier(2GHz-20GHz)	HP	8349B	GTS206	Jun. 29 2017	Jun. 28 2018			
15	Amplifier (18-26GHz)	Rohde & Schwarz	AFS33-18002 650-30-8P-44	GTS218	Jun. 29 2017	Jun. 28 2018			
16	Band filter	Amindeon	82346	GTS219	Mar. 25 2017	Mar. 24 2018			
17	Universal Radio Communication tester	ROHDE&SCHWARZ	CMU 200	GTS538	Jun. 29 2017	Jun. 28 2018			
18	Wideband Radio Communication Tester	ROHDE&SCHWARZ	CMW 500	GTS539	Jun. 29 2017	Jun. 28 2018			

Gen	General used equipment:								
Item	Test Equipment	Manufacturer	Model No.	Inventory No.	Cal.Date (mm-dd-yy)	Cal.Due date (mm-dd-yy)			
1	Barometer	ChangChun	DYM3	GTS257	Jun. 29 2017	Jun. 28 2018			



6 System test configuration

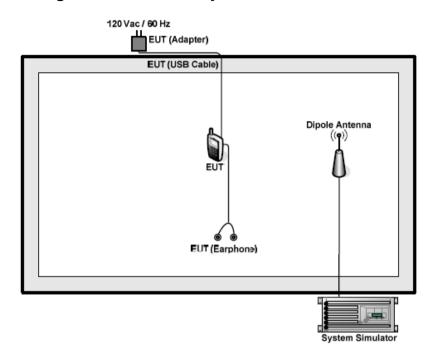
6.1 Test mode

During all testing, EUT is in link mode with base station emulator at maximum power level. The spurious emission measurements were carried out in semi-anechoic chamber with 3-meter test range, and EUT is rotated on three test planes to find out the worst emission.

Test modes						
Band Radiated Conducted						
LTE Band 2	■ QPSK and 16QAM link	■ QPSK and 16QAM link				
LTE Band 4	■ QPSK and 16QAM link	■ QPSK and 16QAM link				
LTE Band 12	■ QPSK and 16QAM link	■ QPSK and 16QAM link				



6.2 Configuration of Tested System





6.3 Conducted Peak Output Power

Test Requirement:	Part 24.232 (c); Part 27.50(c)(10)/(d)(4)		
Test Method:	FCC part2.1046		
Limit:	LTE Band 2: 2W		
	LTE Band 4: 1W		
	LTE Band 12: 3W		
Test setup:	EUT Splitter Communication Tester Power meter		
	Note: Measurement setup for testing on Antenna connector		
Test Procedure:	 The transmitter output port was connected to base station. The RF output of EUT was connected to the power meter by RF cable and attenuator, the path loss was compensated to the 		
	results for each measurement.		
	Set EUT at maximum power through base station.		
	Select lowest, middle, and highest channels for each band and different modulation.		
	5. Measure the maximum burst average power.		
Test Instruments:	Refer to section 6.0 for details		
Test mode:	Refer to section 6.1 for details		
Test results:	Pass		



Measurement Data

	Band 2							
				T	ual output power(dE	3m)		
Bandwidth	Mode	RB Size	RB Offset	Channel 18625 1852.5MHz	Channel 18900 1880.0MHz	Channel 19175 1907.5MHz		
		1	0	21.56	21.54	21.33		
		1	13	21.89	22.92	20.06		
		1	24	21.95	21.37	20.90		
	QPSK	12	0	20.06	22.89	21.23		
		12	6	20.11	21.22	20.36		
		12	13	22.63	21.32	20.72		
5MHz		25	0	20.87	20.40	22.96		
SIVITZ		1	0	21.83	21.56	21.36		
		1	13	20.33	23.02	22.02		
		1	24	20.61	23.03	23.02		
	16QAM	12	0	20.35	21.26	21.93		
		12	6	22.63	22.73	22.93		
		12	13	21.12	21.65	22.94		
		25	0	21.73	21.80	20.43		
				Act	ctual output power(dBm)			
Bandwidth	Mode	RB Size	RB Offset	Channel 18650 1855.0MHz	Channel 18900 1880.0MHz	Channel 19150 1905.0MHz		
	QPSK	1	0	20.96	22.01	22.36		
		1	25	20.13	21.84	22.52		
		1	49	21.34	22.50	21.36		
10MHz		25	0	21.14	22.84	21.54		
		25	13	22.31	21.56	21.81		
		25	25	21.39	23.05	21.63		
		50	0	22.75	20.15	20.47		
				Act	ual output power(dE	3m)		
Bandwidth	Mode	RB Size	RB Offset	Channel 18675 1857.5MHz	Channel 18900 1880.0MHz	Channel 19125 1902.5MHz		
		1	0	21.20	21.64	20.28		
		1	38	22.01	21.47	22.07		
		1	74	22.56	23.04	21.48		
15MHz	QPSK	36	0	21.44	20.29	21.85		
		36	18	22.36	20.37	21.43		
		36	39	22.84	23.02	22.03		
		75	0	20.77	22.42	20.49		



				Act	ual output power(dE	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 18700 1860.0MHz	Channel 18900 1880.0MHz	Channel 19100 1900.0MHz
		1	0	22.86	20.63	21.93
		1	50	21.01	21.83	21.38
		1	99	22.06	22.72	21.52
20MHz	QPSK	50	0	20.52	21.51	21.79
		50	25	20.19	22.08	20.29
		50	50	22.50	21.03	22.83
		100	0	20.78	22.70	20.83
		•	В	and 4		
				Act	ual output power(dE	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 19975 1712.5MHz	Channel 20175 1732.5MHz	Channel 20375 1752.5MHz
		1	0	20.16	22.46	20.93
	QPSK	1	13	21.06	22.49	22.12
		1	24	20.74	22.24	20.26
		12	0	23.00	22.82	22.53
		12	6	20.86	20.33	22.72
		12	13	21.15	22.80	21.43
5MHz		25	0	20.74	20.22	22.89
SIVITZ	16QAM	1	0	22.47	21.24	20.13
		1	13	21.26	20.54	20.91
		1	24	21.44	22.98	20.49
		12	0	22.70	22.44	22.71
		12	6	21.07	20.75	20.82
		12	13	22.92	22.65	20.67
		25	0	21.66	20.97	21.92
				Act	ual output power(dE	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 20000 1715.0MHz	Channel 20175 1732.5MHz	Channel 20350 1750.0MHz
		1	0	22.34	22.10	21.87
		1	25	22.16	22.06	21.06
		1	49	20.39	20.63	20.21
10MHz	QPSK	25	0	20.23	21.22	20.35
		25	13	21.65	22.90	20.33
		25	25	22.04	20.53	21.63
		50	0	20.78	22.06	22.90



				Act	ual output power(dE	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 20025 1717.5MHz	Channel 20175 1732.5MHz	Channel 20325 1747.5MHz
		1	0	22.39	22.18	22.92
		1	38	21.71	22.90	22.01
		1	74	20.88	21.85	21.93
15MHz	QPSK	36	0	22.19	22.01	21.06
		36	18	21.67	20.78	20.26
		36	39	21.64	21.37	22.89
		75	0	21.39	21.55	22.57
				Act	ual output power(dE	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 20050 1720.0MHz	Channel 20175 1732.5MHz	Channel 20300 1745.0MHz
		1	0	22.93	20.98	22.14
		1	50	20.33	21.88	22.33
	QPSK	1	99	22.93	21.37	20.41
20MHz		50	0	21.56	20.84	22.80
		50	25	22.86	21.53	22.31
		50	50	21.78	21.13	21.17
		100	0	20.49	22.48	21.28
			Ва	nd 12		
				Act	ual output power(dE	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 23035 701.5MHz	Channel 23095 707.5MHz	Channel 23155 713.5MHz
		1	0	22.69	22.53	21.78
		1	13	20.85	20.97	20.35
		1	24	20.84	21.00	22.11
	QPSK	12	0	21.23	23.05	21.50
		12	6	22.35	20.39	22.98
		12	13	20.71	21.13	21.61
EMU-		25	0	20.17	22.16	20.80
5MHz		1	0	21.03	20.81	22.03
		1	13	21.54	22.72	22.36
		1	24	22.37	22.60	20.60
	16QAM	12	0	20.92	20.30	21.00
		12	6	22.14	20.24	21.49
		12	13	22.90	22.86	22.37
		25	0	21.11	21.96	21.71



	Mode	RB Size	RB Offset	Actual output power(dBm)			
Bandwidth				Channel 23060 704.0MHz	Channel 23095 707.5MHz	Channel 23130 711.0MHz	
10MHz	QPSK	1	0	22.66	22.94	20.96	
		1	25	21.00	21.23	21.45	
		1	49	20.86	22.14	20.40	
		25	0	22.60	20.39	20.41	
		25	13	21.06	20.16	22.65	
		25	25	21.79	20.36	20.99	
		50	0	21.74	22.79	21.67	



6.4 Peak-to-Average Ratio

Test Requirement:	FCC part24.232(d)					
Test Method:	FCC part2.1046					
Limit:	13db					
Test setup:	EUT Splitter Communication Tester					
	Power meter Note: Measurement setup for testing on Antenna connector					
Test Procedure:	 The transmitter output port was connected to base station. The RF output of EUT was connected to the power meter by RF cable and attenuator, the path loss was compensated to the results for each measurement. Set EUT at maximum power through base station. Select lowest, middle, and highest channels for each band and different modulation. Measure the maximum burst average power. Record the maximum peak-to-average ratio value. 					
Test Instruments:	Refer to section 6.0 for details					
Test mode:	Refer to section 6.1 for details					
Test results:	Pass					



QPSK mode:

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Test Band		Peal	k to Average F	Limit			
	Test mode		(dB)	(dB)	Result		
		Low Ch. Middle Ch.		High Ch.	(ab)		
	LTE 5MHz Bandwidth	4.66	4.82	3.85	13	PASS	
	LTE 10MHz Bandwidth	4.75	5.11	4.91	13	PASS	
LTE Band 2	LTE 15MHz Bandwidth	5.37	5.57	5.70	13	PASS	
LT Dana 2	LTE 20MHz Bandwidth	6.12	6.24	6.27	13	PASS	
LTE Band 4	LTE 5MHz Bandwidth	5.14	5.17	4.90	13	PASS	
	LTE 10MHz Bandwidth	4.94	5.16	4.96	13	PASS	
	LTE 15MHz Bandwidth	5.56	5.53	5.58	13	PASS	
	LTE 20MHz Bandwidth	6.06	6.06	6.14	13	PASS	
LTE Band 12	LTE 5MHz Bandwidth	4.79	4.51	4.54	13	PASS	
	LTE 10MHz Bandwidth	4.39	4.82	4.85	13	PASS	

16QAM mode:

Test Band	Test mode	Peak to Average Ratio (dB)			Limit (dB)	Result
		Low Ch.	Middle Ch.	High Ch.	(45)	
LTE Band 2	LTE 5MHz Bandwidth	4.56	4.77	3.87	13	PASS
LTE Band 4	LTE 5MHz Bandwidth	5.18	5.17	4.84	13	PASS
LTE Band 12	LTE 5MHz Bandwidth	4.78	4.51	4.54	13	PASS

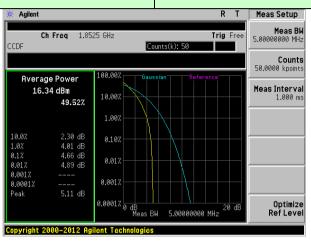


Test plot as follows:

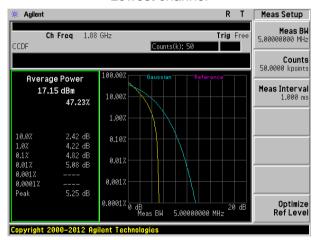
QPSK mode:

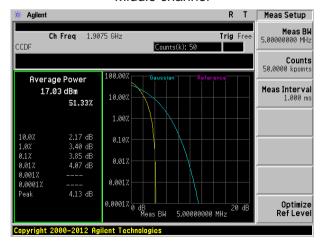
Test band: LTE Band 2

Channel Bandwidth: 5MHz



Lowest channel



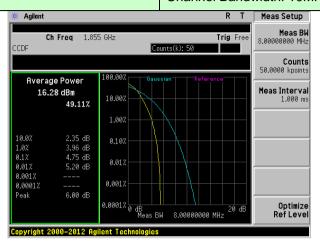


Highest channel

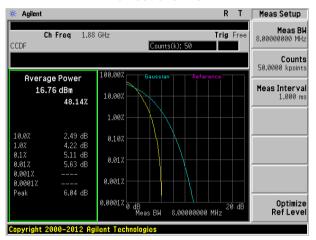


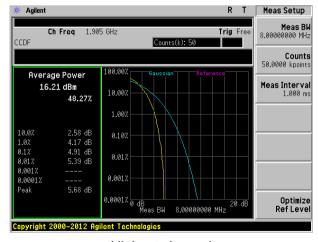
Test band: LTE Band 2

Channel Bandwidth: 10MHz



Lowest channel





Highest channel

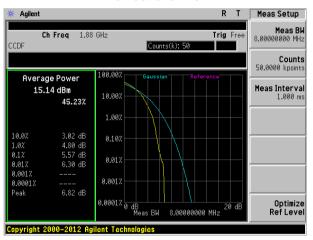


Test band: LTE Band 2

Channel Bandwidth: 15MHz



Lowest channel



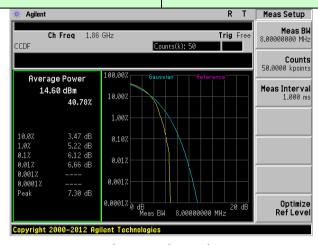


Highest channel

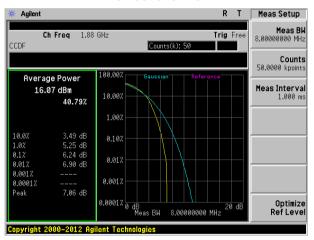


Test band: LTE Band 2

Channel Bandwidth: 20MHz



Lowest channel



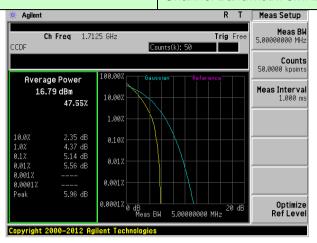


Highest channel

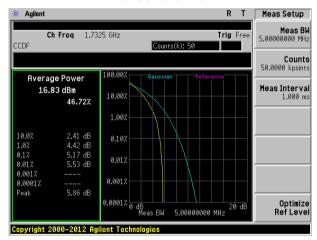


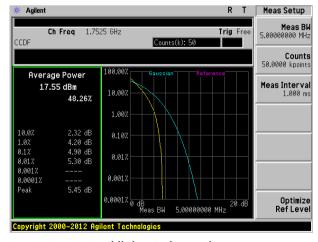
Test band: LTE Band 4

Channel Bandwidth: 5MHz



Lowest channel



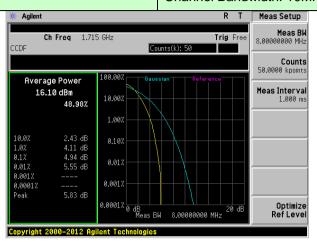


Highest channel

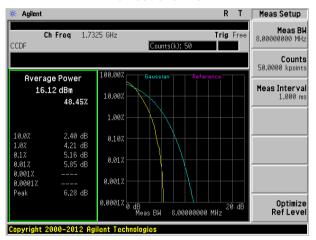


Test band: LTE Band 4

Channel Bandwidth: 10MHz



Lowest channel



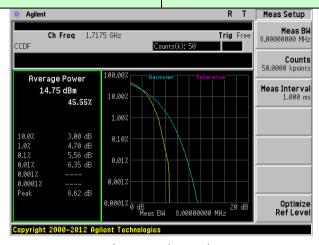


Highest channel

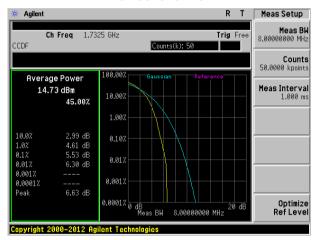


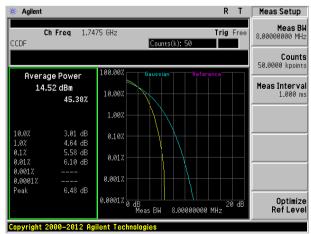
Test band: LTE Band 4

Channel Bandwidth: 15MHz



Lowest channel



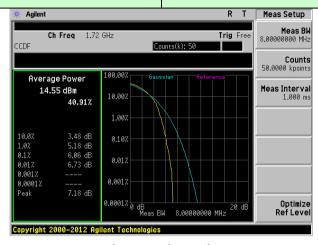


Highest channel

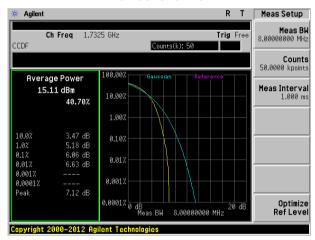


Test band: LTE Band 4

Channel Bandwidth: 20MHz



Lowest channel





Highest channel

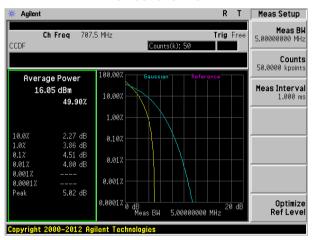


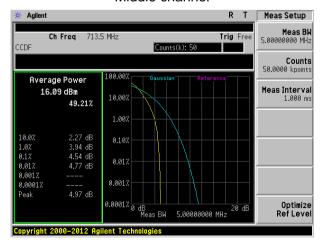
Test band: LTE Band 12

Channel Bandwidth: 5MHz



Lowest channel



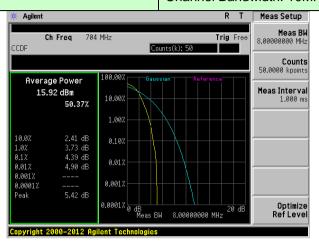


Highest channel

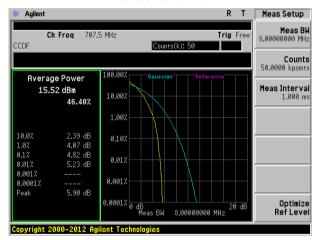


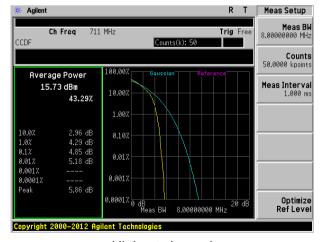
Test band: LTE Band 12

Channel Bandwidth: 10MHz



Lowest channel





Highest channel

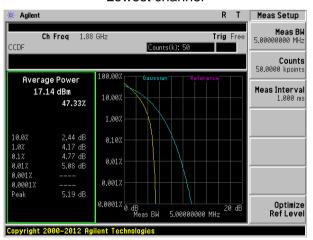


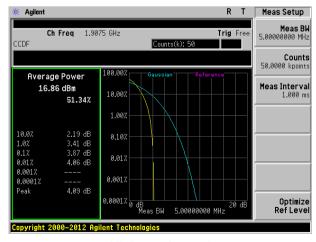
16QAM mode:

Test band: LTE Band 2 Channel Bandwidth: 5MHz



Lowest channel



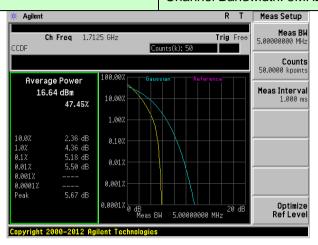


Highest channel

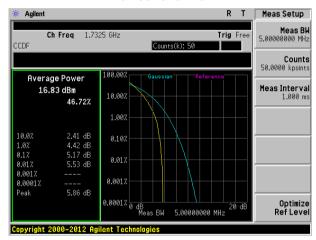


Test band: LTE Band 4

Channel Bandwidth: 5MHz



Lowest channel





Highest channel

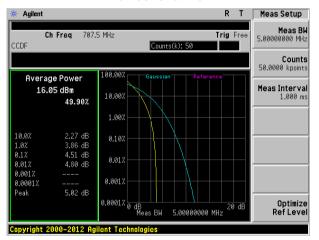


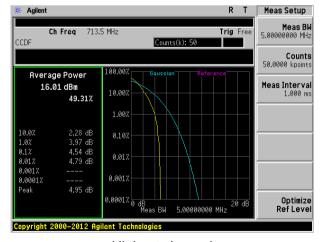
Test band: LTE Band 12

Channel Bandwidth: 5MHz



Lowest channel





Highest channel



6.5 Occupy Bandwidth

Test Requirement:	Part 24.238; FCC Part 27.53(h)/(g)					
Test Method:	FCC part2.1049					
Test setup:	Splitter Communication Tester SPA SPA Note: Measurement setup for testing on Antenna connector					
Test Procedure:	 The EUT's output RF connector was connected with a short cable to the spectrum analyzer RBW was set to about 1% of emission BW, VBW= 3 times RBW. -26dBc display line was placed on the screen (or 99% bandwidth), the occupied bandwidth is the delta frequency between the two points where the display line intersects the signal trace. 					
Test Instruments:	Refer to section 6.0 for details					
Test mode:	Refer to section 6.1 for details					
Test results:	Pass					



Measurement Data

QPSK mode:

QPSK mode:	Channel	Ohamal	RB Co	onfigure	99% Occupy	-26dB bandwidth (KHz)
EUT Mode	Bandwidth	Channel	RB Size	RB Offset	bandwidth (KHz)	
		Low range	25	0	4514.20	4863.00
	5MHz	Mid range	25	0	4519.00	5052.00
		High range	25	0	4525.00	5297.00
		Low range	50	0	8931.70	9693.00
	10MHz	Mid range	50	0	8942.50	9642.00
LTE Band 2		High range	50	0	8930.60	9677.00
LIE Ballu Z		Low range	75	0	13458.80	14803.00
	15MHz	Mid range	75	0	13368.10	14595.00
		High range	75	0	13436.80	14681.00
		Low range	100	0	17879.60	19282.00
	20MHz	Mid range	100	0	17807.70	19019.00
		High range	100	0	17924.50	19480.00
EUT Mode	Channel	Channel	RB Configure		99% Occupy	-26dB
EUT Mode	Bandwidth	Channel	RB Size	RB Offset	bandwidth (KHz)	bandwidth (KHz)
	5MHz	Low range	25	0	4503.50	5012.00
		Mid range	25	0	4517.70	4959.00
		High range	25	0	4512.60	4905.00
		Low range	50	0	8907.80	9599.00
	10MHz	Mid range	50	0	8951.50	9793.00
LTE Band 4		High range	50	0	8925.60	9677.00
LTE Ballu 4	15MHz	Low range	75	0	13393.60	14670.00
		Mid range	75	0	13441.30	14757.00
		High range	75	0	13417.50	14569.00
	20MHz	Low range	100	0	17823.30	19119.00
		Mid range	100	0	17856.80	19329.00
		High range	100	0	17850.80	19243.00
FUT Mode	Channel Bandwidth	Observati	RB Configure		99% Occupy bandwidth	-26dB
EUT Mode		Channel	RB Size	RB Offset	(KHz)	bandwidth (KHz)
LTE Band 12		Low range	25	0	4502.70	4956.00
	5MHz	Mid range	25	0	4534.90	5080.00
		High range	25	0	4487.60	4955.00
LIL Dallu 12		Low range	50	0	8851.70	9538.00
	10MHz	Mid range	50	0	8969.80	9751.00
		High range	50	0	8957.80	9582.00



16QAM mode:

EUT Mode	Channel Bandwidth	Channel	RB Co	onfigure	99% Occupy bandwidth	-26dB bandwidth (KHz)					
EOT Mode			RB Size	RB Offset	(KHz)						
		Low range	25	0	4509.80	5050.00					
LTE Band 2	5MHz	Mid range	25	0	4515.50	5042.00					
		High range	25	0	4521.00	5761.00					
EUT Mode	Channel Bandwidth	Channel	RB Configure		99% Occupy bandwidth	-26dB					
EOT Mode		Charine	RB Size	RB Offset	(KHz)	bandwidth (KHz)					
	5MHz	Low range	25	0	4507.10	5017.00					
LTE Band 4		Mid range	25	0	4520.90	4874.00					
		High range	25	0	4501.60	4999.00					
	Channel Bandwidth			Channel	Channel	Channel	01	RB Co	onfigure	99% Occupy	-26dB
EUT Mode				Channel	RB Size	RB Offset	bandwidth (KHz)	bandwidth (KHz)			
LTE Band 12	5MHz		Low range	25	0	4506.90	4994.00				
		Mid range	25	0	4532.20	5015.00					
		High range	25	0	4481.10	4956.00					

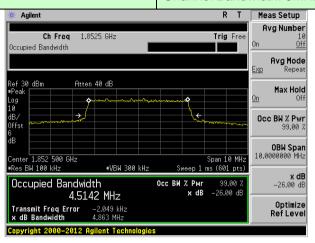


Test plot as follows:

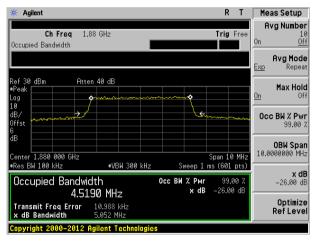
QPSK mode:

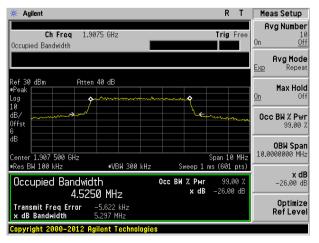
Test band: LTE Band 2

Channel Bandwidth: 5MHz



Lowest channel



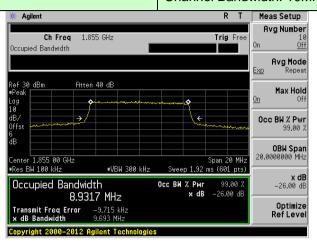


Highest channel

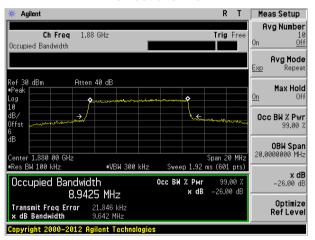


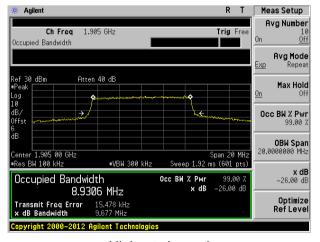
Test band: LTE Band 2

Channel Bandwidth: 10MHz



Lowest channel



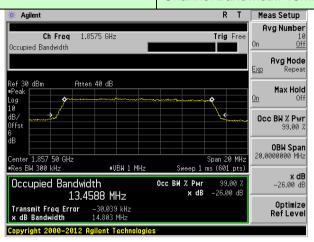


Highest channel

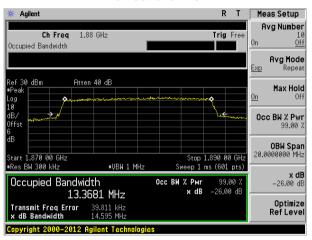


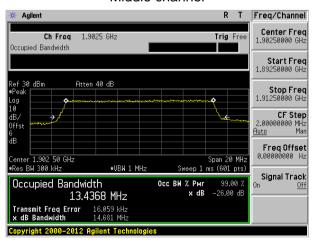
Test band: LTE Band 2

Channel Bandwidth: 15MHz



Lowest channel



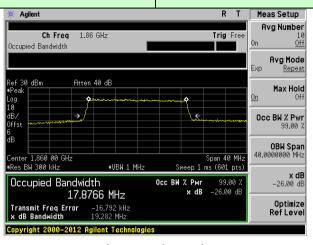


Highest channel

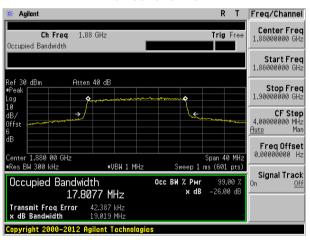


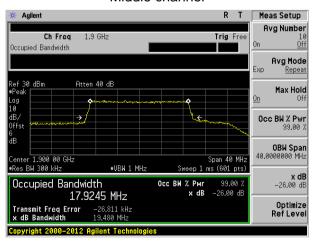
Test band: LTE Band 2

Channel Bandwidth: 20MHz



Lowest channel



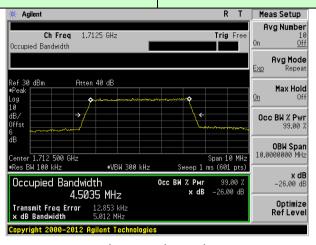


Highest channel

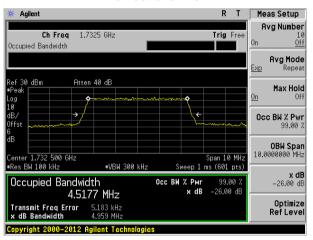


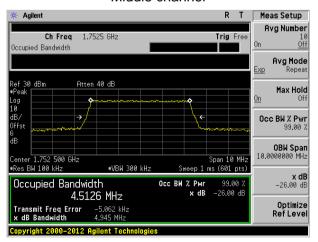
Test band: LTE Band 4

Channel Bandwidth: 5MHz



Lowest channel



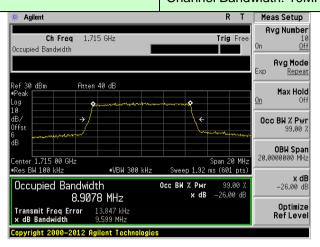


Highest channel

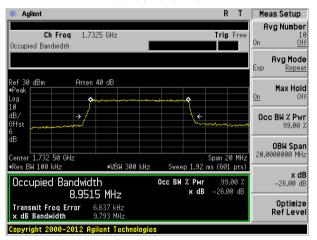


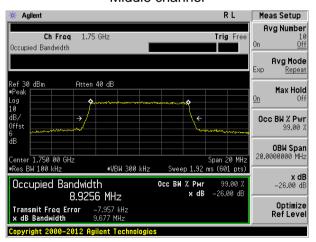
Test band: LTE Band 4

Channel Bandwidth: 10MHz



Lowest channel



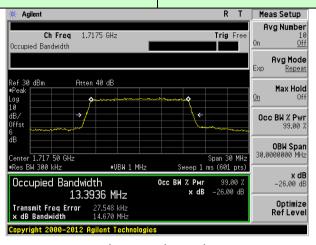


Highest channel

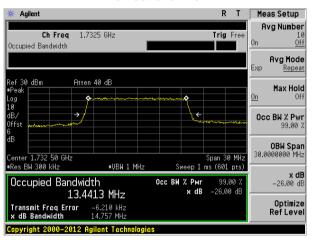


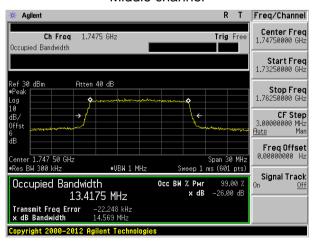
Test band: LTE Band 4

Channel Bandwidth: 15MHz



Lowest channel



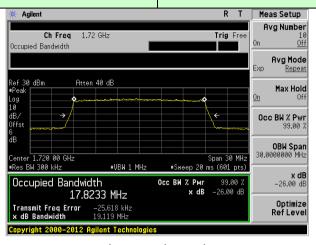


Highest channel

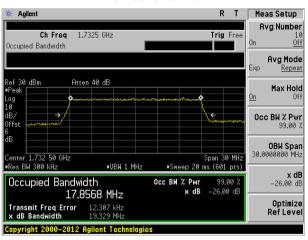


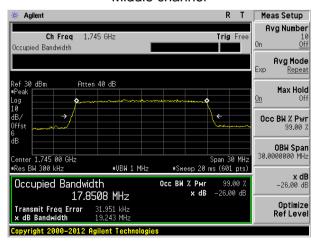
Test band: LTE Band 4

Channel Bandwidth: 20MHz



Lowest channel



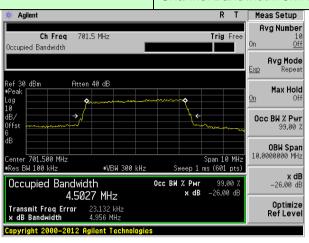


Highest channel

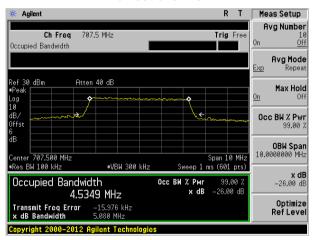


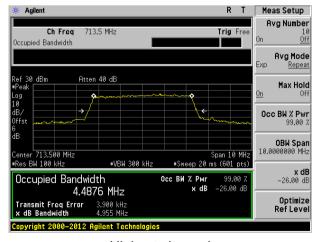
Test band: LTE Band 12

Channel Bandwidth: 5MHz



Lowest channel



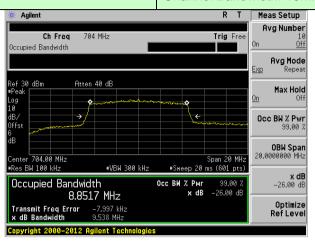


Highest channel

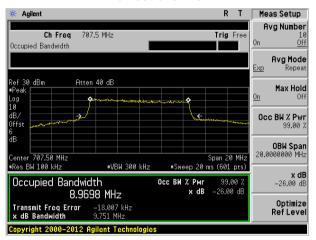


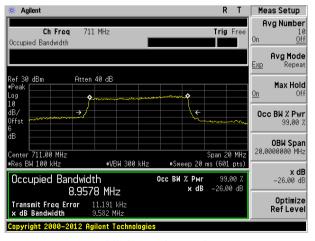
Test band: LTE Band 12

Channel Bandwidth: 10MHz



Lowest channel





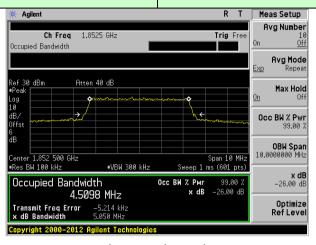
Highest channel



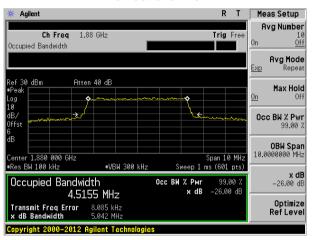
16QAM mode:

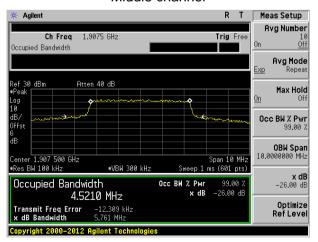
Test band: LTE Band 2

Channel Bandwidth: 5MHz



Lowest channel



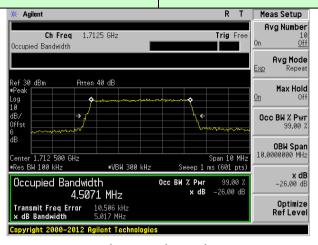


Highest channel

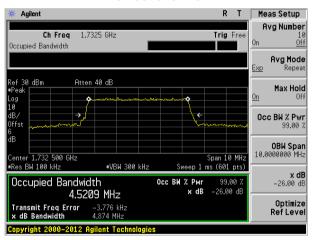


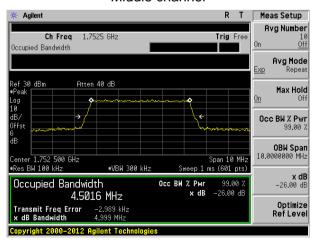
Test band: LTE Band 4

Channel Bandwidth: 5MHz



Lowest channel



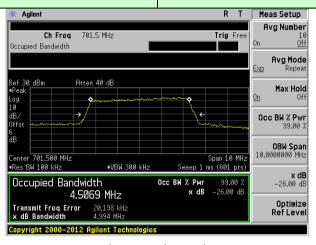


Highest channel

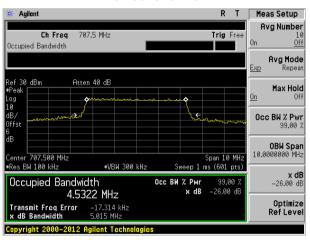


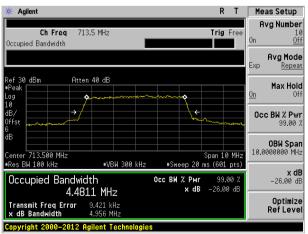
Test band: LTE Band 12

Channel Bandwidth: 5MHz



Lowest channel





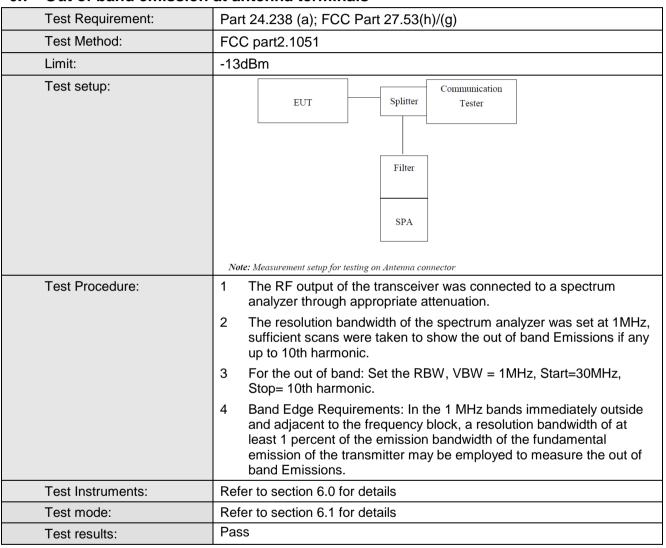
Highest channel



6.6 MODULATION CHARACTERISTIC

According to FCC § 2.1047(d), Part 27 there is no specific requirement for digital modulation, therefore modulation characteristic is not presented.

6.7 Out of band emission at antenna terminals

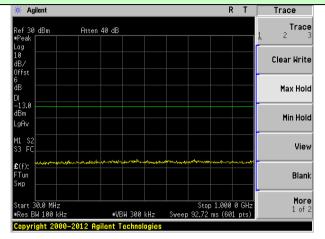


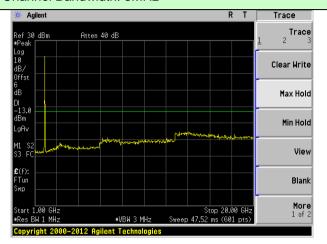
Test plot as follows:



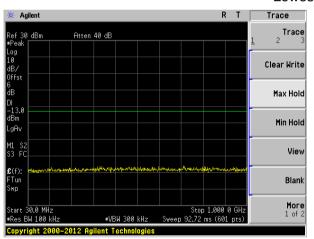
QPSK mode:

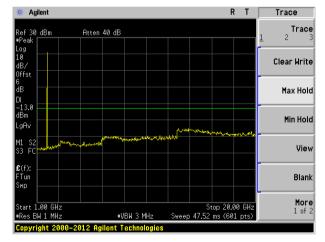
Test Mode: LTE Band 2 Channel Bandwidth: 5MHz



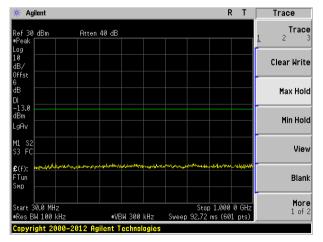


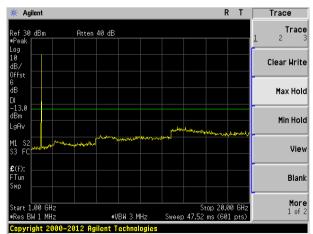
Lowest channel





Middle channel

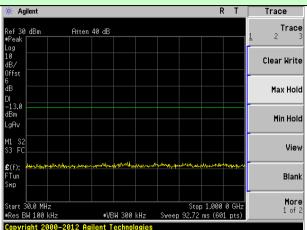




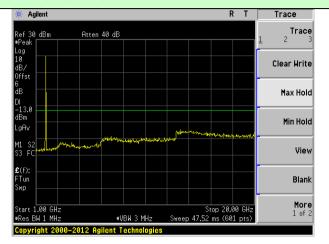
Highest channel



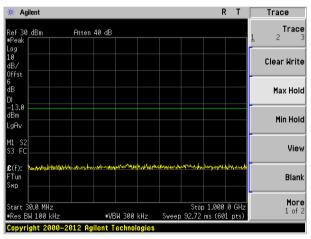
Test Mode: LTE Band 2 ** Agilent

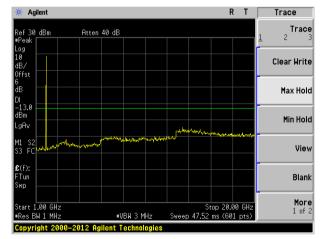


Channel Bandwidth: 10MHz

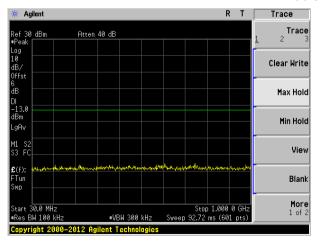


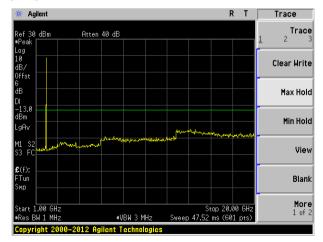
Lowest channel





Middle channel



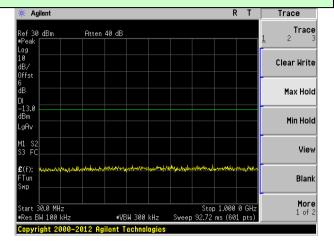


Highest channel



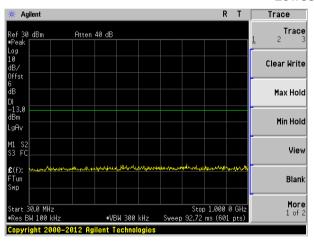
Test Mode: LTE Band 2

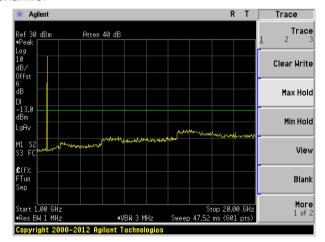




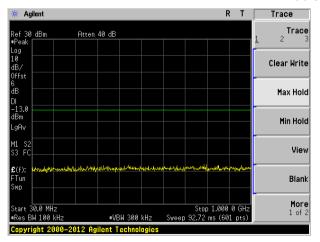


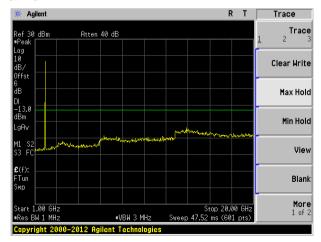
Lowest channel





Middle channel



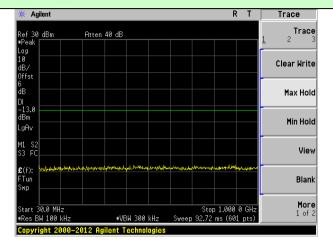


Highest channel



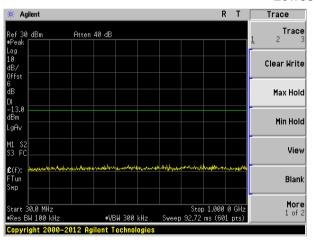
Test Mode: LTE Band 2

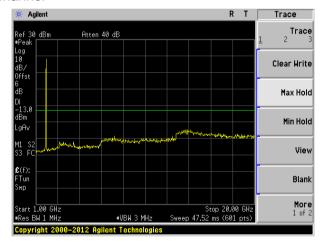
Channel Bandwidth: 20MHz



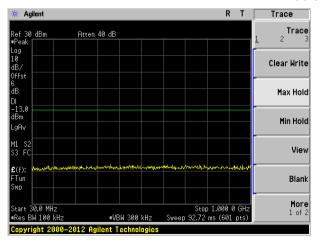


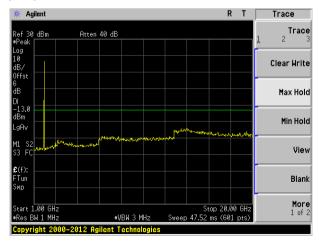
Lowest channel





Middle channel





Highest channel



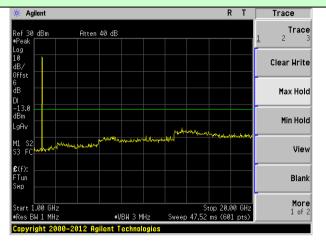
Test Mode: LTE Band 4 # Agilent R T Trace Ref 30 dBm Atten 40 dB Peak Log 10 Clear Write 0 dB/ 0 dB/

#UBW 300 kHz

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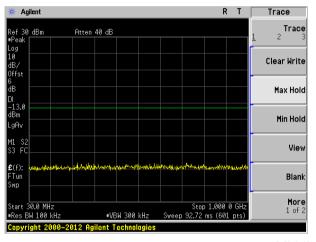
Stop 1.000 0 GH: Sweep 92.72 ms (601 pts)

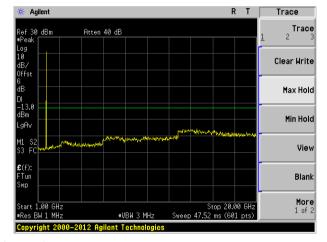
Channel Bandwidth: 5MHz



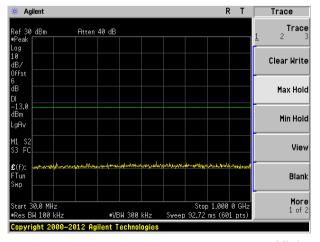
Lowest channel

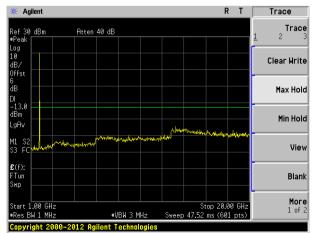
More 1 of 2





Middle channel



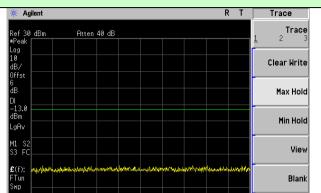


Highest channel



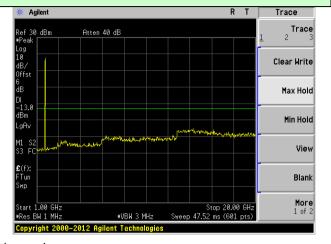
Test Mode: LTE Band 4

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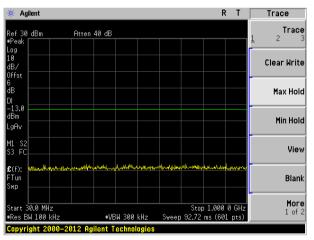
Stop 1.000 0 GH: 92.72 ms (601 pts)

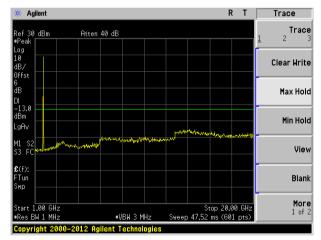
Channel Bandwidth: 10MHz



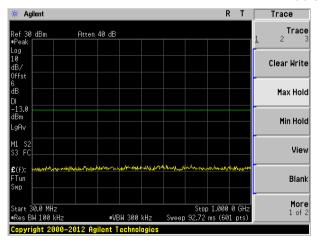
Lowest channel

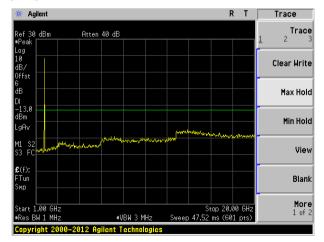
More 1 of 2





Middle channel





Highest channel



Test Mode: LTE Band 4

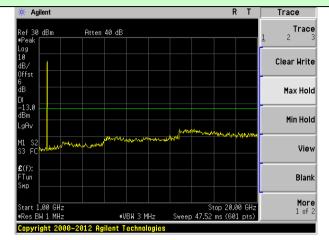
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£(f):



Stop 1.000 0 GH: eep 92.72 ms (601 pts)

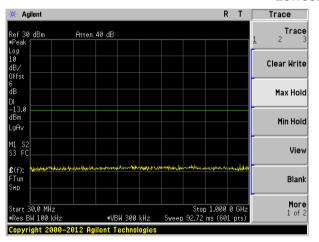
Channel Bandwidth: 15MHz

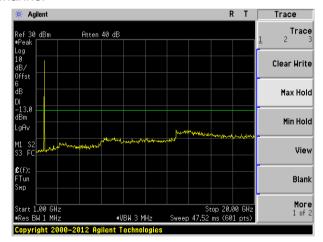


Lowest channel

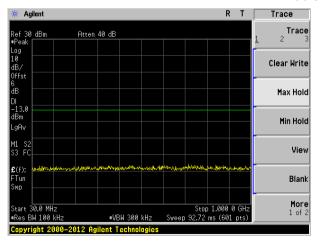
Blank

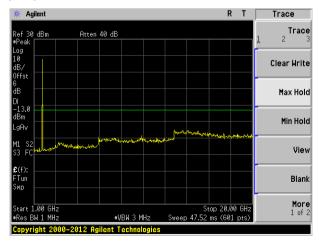
More 1 of 2





Middle channel



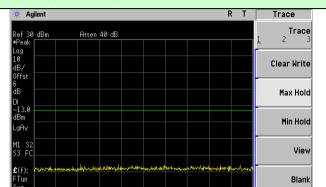


Highest channel



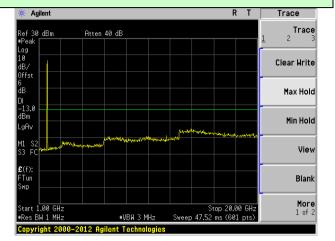
Test Mode: LTE Band 4

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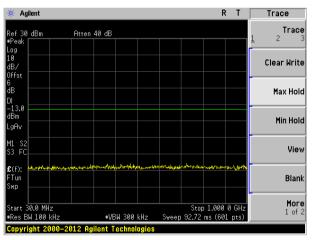
Stop 1.000 0 GH: 92.72 ms (601 pts)

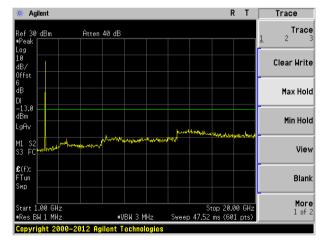
Channel Bandwidth: 20MHz



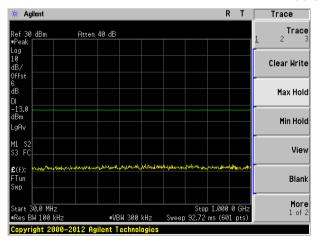
Lowest channel

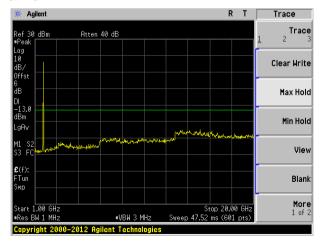
More 1 of 2





Middle channel



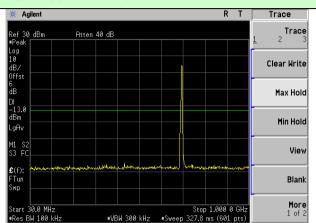


Highest channel



Test Mode: LTE Band 12

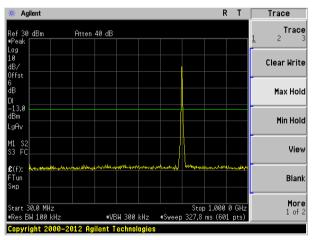
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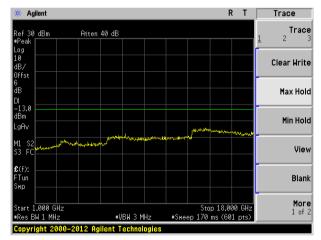


Channel Bandwidth: 5MHz

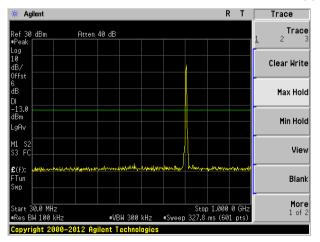


Lowest channel





Middle channel

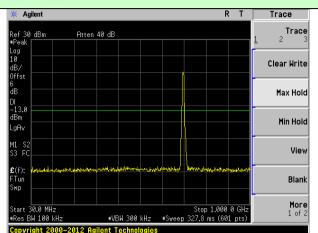




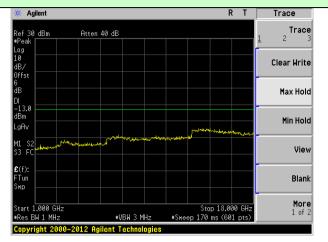
Highest channel



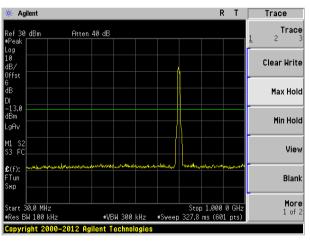
Test Mode: LTE Band 12

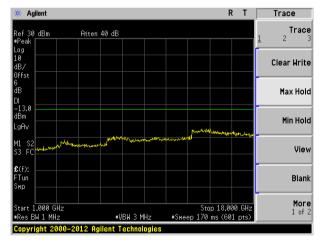


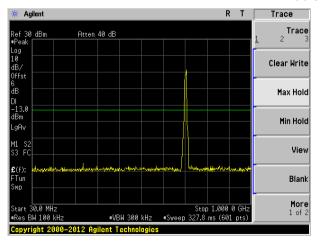
Channel Bandwidth: 10MHz

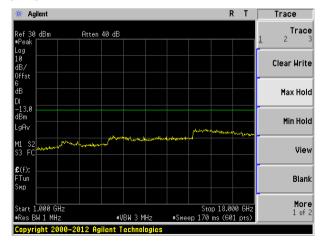


Lowest channel







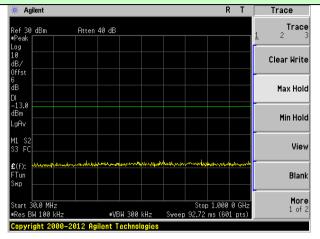


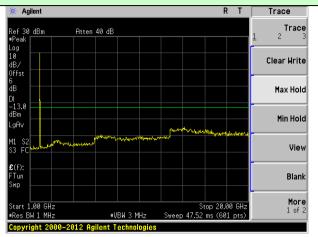
Highest channel



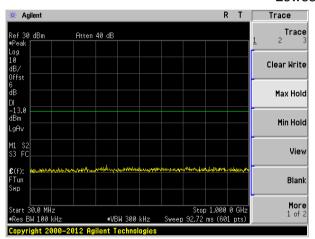
16QAM mode:

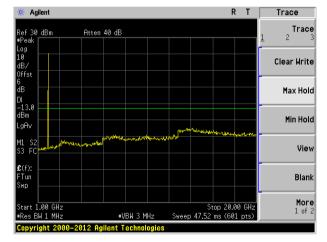
Test Mode: LTE Band 2 Channel Bandwidth: 5MHz



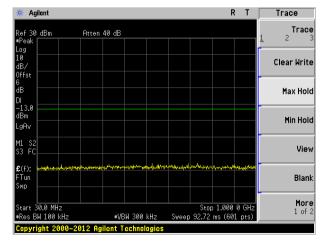


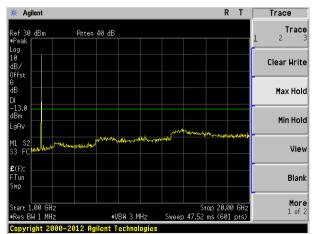
Lowest channel





Middle channel





Highest channel



Test Mode: LTE Band 4 # Agilent R T Trace Ref 30 dBm Atten 40 dB Peak Log 10 dB/ Offst 6 dB DI -13.0 dBm LgRv M1 \$2 S3 FC £(f): FTun Swp Blank

#UBW 300 kHz

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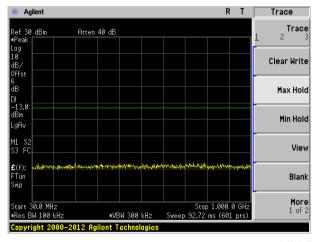
Stop 1.000 0 GH: Sweep 92.72 ms (601 pts)

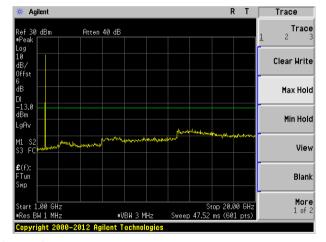
Channel Bandwidth: 5MHz



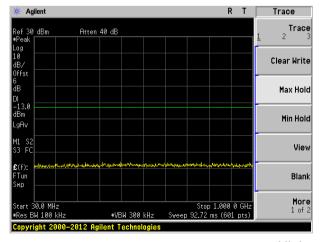
Lowest channel

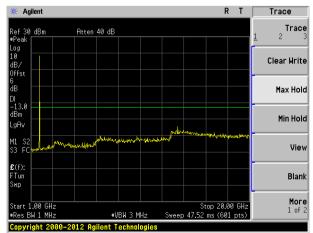
More 1 of 2





Middle channel

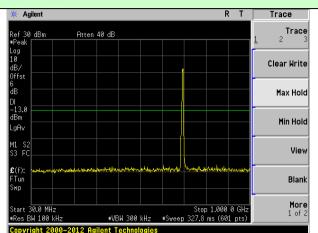




Highest channel



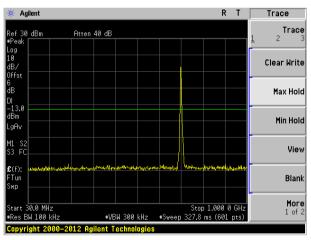
Test Mode: LTE Band 12

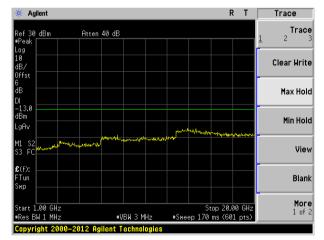


Channel Bandwidth: 5MHz

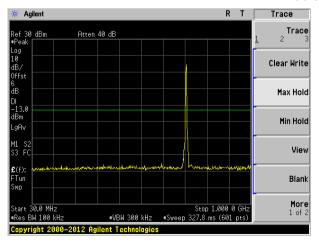


Lowest channel





Middle channel



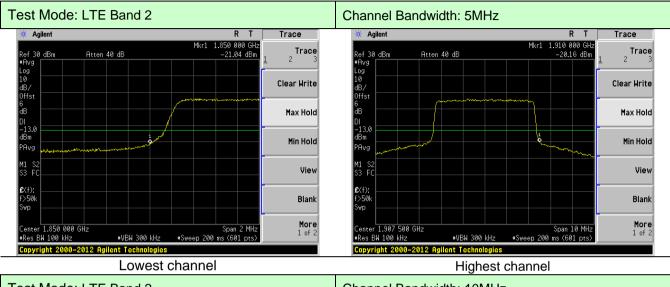


Highest channel



Band Edge:

QPSK mode:



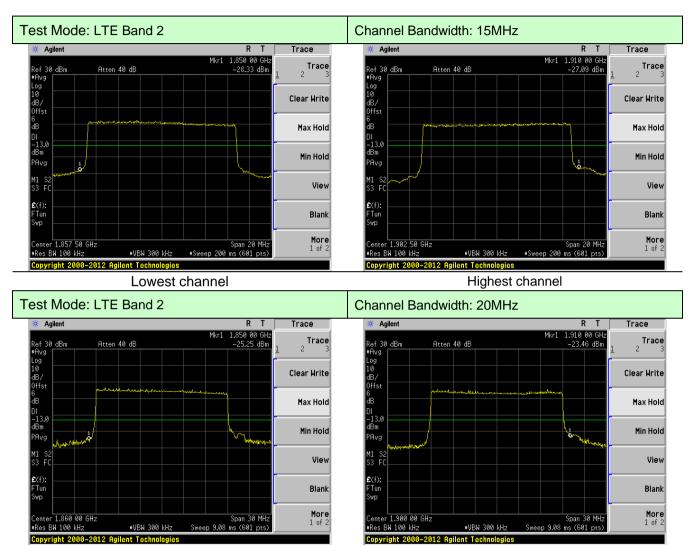
Test Mode: LTE Band 2 Channel Bandwidth: 10MHz Agilent R T * Agilent Trace Atten 40 dB Ref 30 dBm Atten 40 dB lef 30 dBm Clear Write Max Hold Min Hold View Blank More 1 of 2 Span 20 MHz #Sweep 200 ms (601 pts) Center 1.905 00 GHz ≢Res BW 100 kHz #VBW 300 kHz Copyright 2000-2012 Agilent Technologies

R T 1.910 00 GHz -24.90 dBm Trace Clear Write Max Hold Min Hold View Blank More 1 of 2 Span 20 MHz #Sweep 200 ms (601 pts) #VBW 300 kHz Copyright 2000-2012 Agilent Technologies

Lowest channel

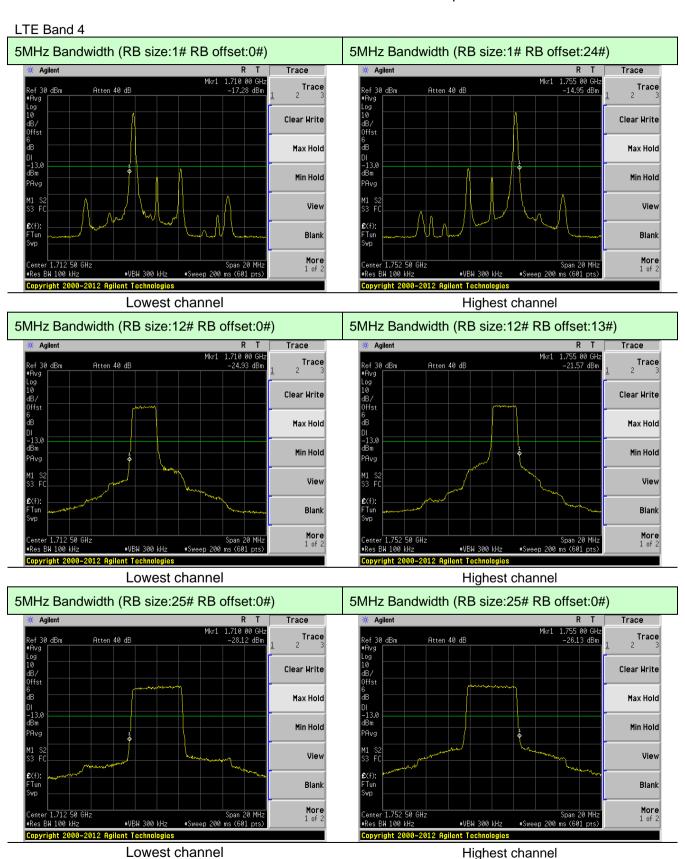
Highest channel





Lowest channel Highest channel



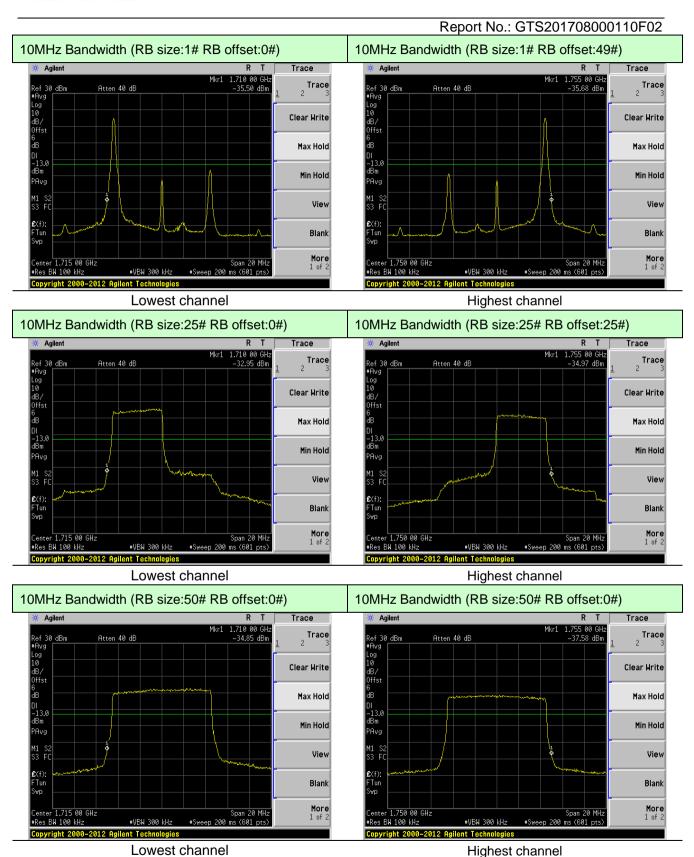


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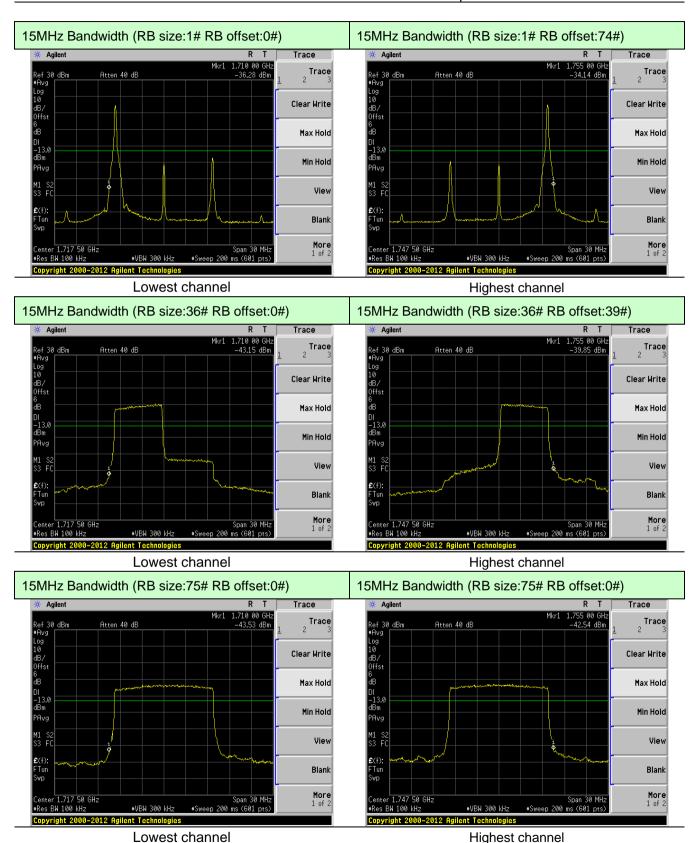
No. 301-309, 3/F., Jinyuan Business Building, No.2, Laodong Industrial Zone,

Xixiang Road, Baoan District, Shenzhen, Guangdong, China 518102







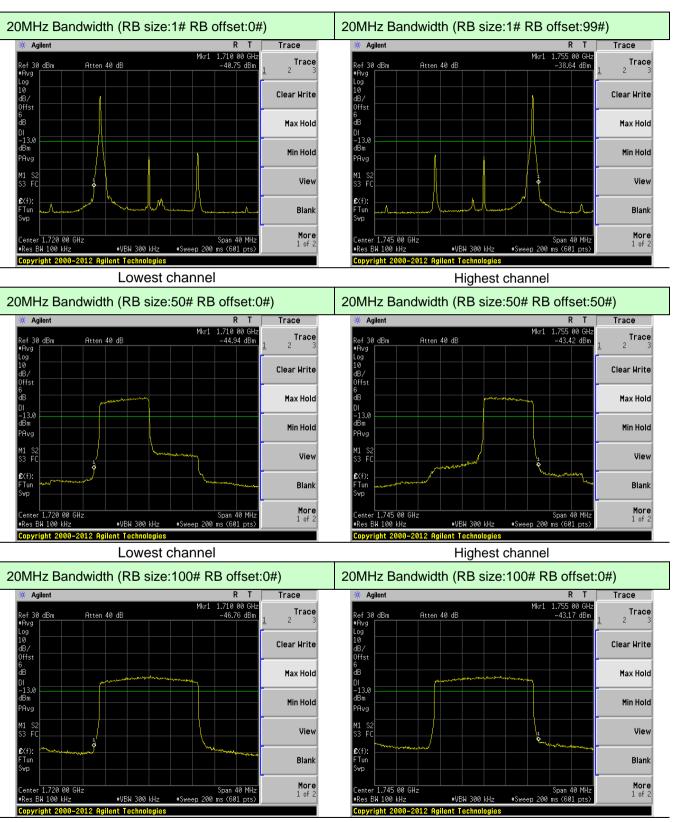


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Xixiang Road, Baoan District, Shenzhen, Guangdong, China 518102





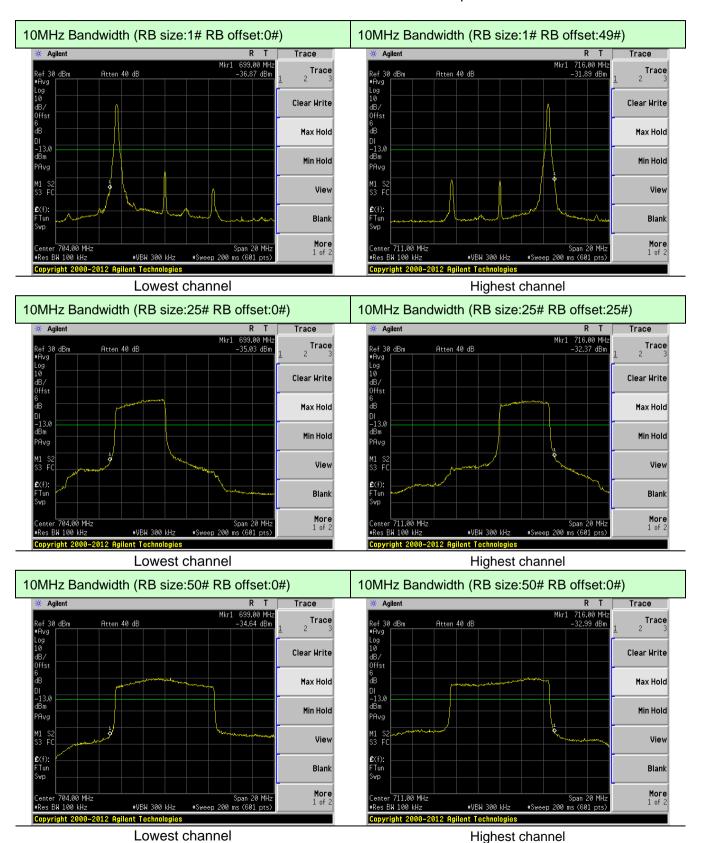
Lowest channel Highest channel



LTE Band 12(QPSK mode): 5MHz Bandwidth (RB size:1# RB offset:0#) 5MHz Bandwidth (RB size:1# RB offset:24#) * Agilent R T Trace 🔆 Agilent R T 699.000 MHz -21.69 dBm 716.000 MHz –20.48 dBm Trace Trace Atten 40 dB Ref 30 dBm Atten 40 dB Clear Write Clear Write Max Hold Max Hold Min Hold Min Hold View View Blank Blank More 1 of 2 Span 10 MH #Sweep 200 ms (601 pts Span 10 MH #Sweep 200 ms (601 pts #VBW 300 kHz #VBW 300 kHz Copyright 2000-2012 Agilent Technologies Copyright 2000-2012 Agilent Technologies Lowest channel Highest channel 5MHz Bandwidth (RB size:12# RB offset:0#) 5MHz Bandwidth (RB size:12# RB offset:13#) * Agilent * Agilent Trace Trace 699,000 MH 716.000 MH: -24.97 dBm Atten 40 dB Atten 40 dB Clear Write Clear Write Max Hold Max Hold Min Hold Min Hold View View Blank Blank More 1 nf 2 More 1 of 2 #VBW 300 kHz #VBW 300 kHz Lowest channel Highest channel 5MHz Bandwidth (RB size:25# RB offset:0#) 5MHz Bandwidth (RB size:25# RB offset:0#) Trace 699.000 MHz -32.19 dBm 716.000 MHz -28.92 dBm ef 30 dBm Atten 40 dB Ref 30 dBm Atten 40 dB Clear Write Clear Write Max Hold Max Hold Min Hold Min Hold View View Blank Blank More 1 of 2 Center 713.500 MHz •Res BW 100 kHz Span 10 MHz Sweep 200 ms (601 pts) Span 10 MHz #Sweep 200 ms (601 pts) #VBW 300 kHz ■Res BW 100 kHz #VBW 300 kHz Copyright 2000-2012 Agilent Technologies Copyright 2000-2012 Agilent Technologies

Lowest channel Highest channel





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More 1 of 2

LTE Band 2(16QAM mode): 5MHz Bandwidth (RB size:1# RB offset:0#) 5MHz Bandwidth (RB size:1# RB offset:24#) * Agilent Agilent Trace Trace 1.850 000 GHz -21.68 dBm Mkr1 1.910 000 GHz -20.22 dBm Trace Ref 30 dBm Atten 40 dB Trace Ref 30 dBm •Ava Atten 40 dB Clear Write Clear Write Max Hold Max Hold Min Hold Min Hold View View Blank Blank

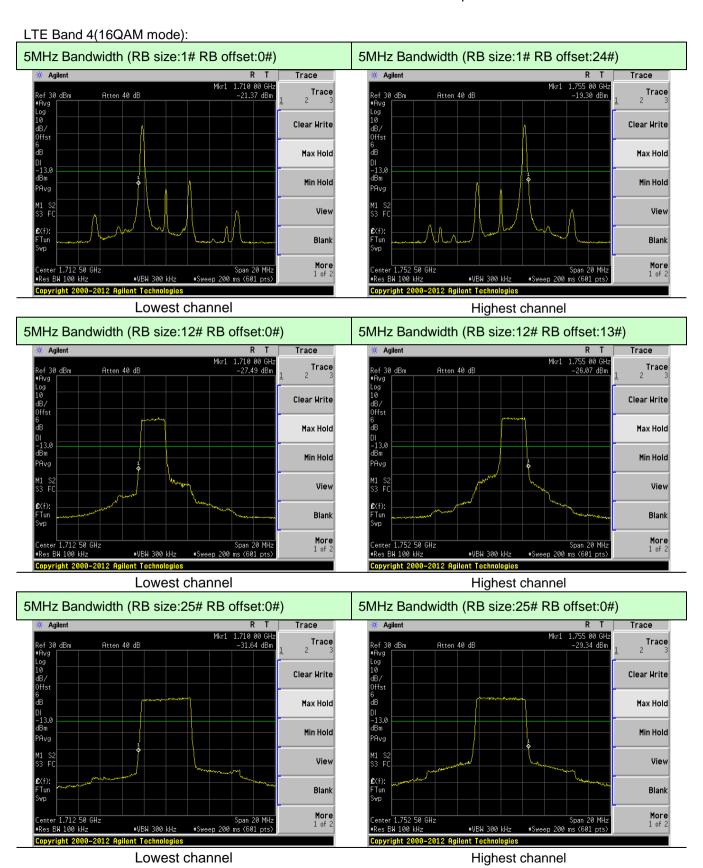
Lowest channel Highest channel

Center 1.907 500 GHz •Res BW 100 kHz

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More 1 of 2



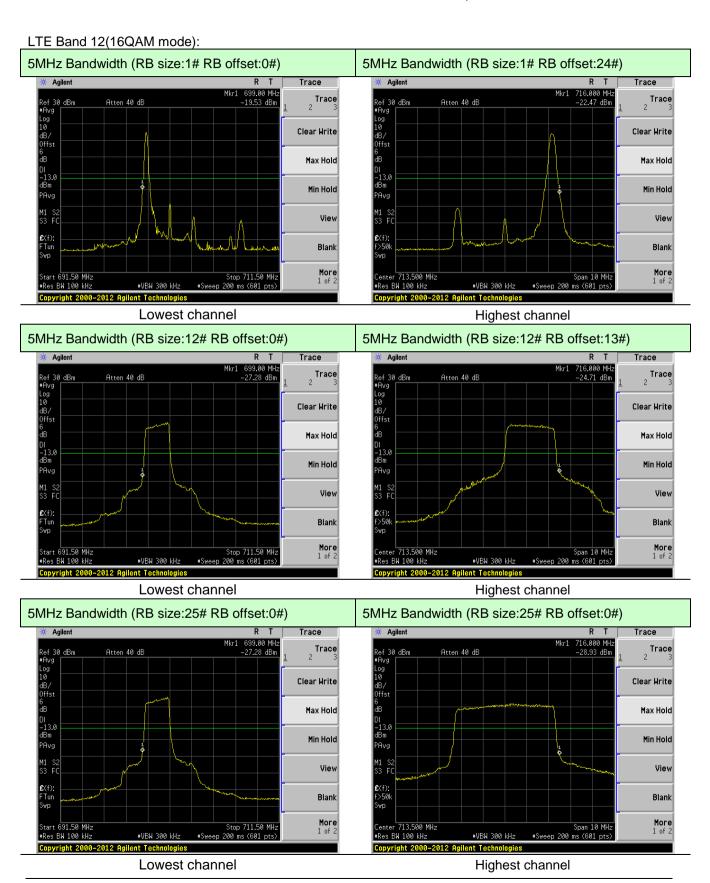


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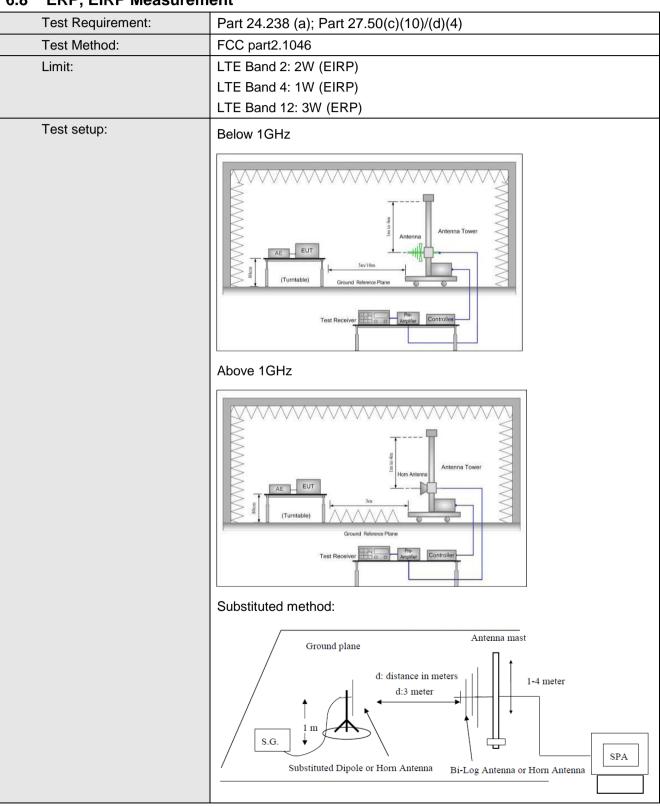
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6.8 ERP, EIRP Measurement





Test Procedure:	The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.
	2. During the measurement, the EUT was communication with the station. The highest emission was recorded with the rotation of the turntable and the lowering of the test antenna from 4m to 1m. The reading was recorded and the field strength (E in dBuV/m) was calculated.
	3. ERP in frequency band 777–787MHz were measured using a substitution method. The EUT was replaced by dipole antenna connected, the S.G. output was recorded and ERP was calculated asfollows:
	ERP = S.G. output (dBm) + Antenna Gain (dBd) – Cable Loss (dB)
	4. EIRP in frequency band 1710–1755MHz were measured using a substitution method. The EUT was replaced by or horn antenna connected, the S.G. output was recorded and EIRP was calculated as follows:
	EIRP = S.G. output (dBm) + Antenna Gain (dBi) – Cable Loss (dB)
Test Instruments:	Refer to section 6.0 for details
Test mode:	Refer to section 6.1 for details
Test results:	Pass

Measurement Data



QPSK mode:

EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.56		
		11	Н	20.52		Davis
	Lawast	E1	V	22.20	22.00	
	Lowest		Н	19.85	33.00	Pass
		E2	V	21.44		
		E2	Н	18.59		
		Н	V	22.57		Pass
			Н	19.84	33.00	
LTE Band 2	Middle	E1	V	22.08		
(5MHz)	Middle		Н	19.63		
		E2	V	21.94		
		E2	Н	18.83		
		Н	V	22.29		
		П	Н	20.01		
	Llighoot	E1	V	22.04	22.00	Door
Highest	nignest	E1	Н	19.72	33.00	Pass
			V	21.80		
		E2	Н	19.22		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP (dBm)	Limit (dBm)	Result
		Н	V	22.66		
		П	Н	20.64		_
	1	- 4	V	22.34	00.00	
	Lowest	E1	Н	19.99	33.00	Pass
		F0	V	21.60		
		E2	Н	18.77		
		Н	V	22.72		Pass
	Middle		Н	20.02	33.00	
LTE Band 2		E1	V	22.28		
(10MHz)	ivildale		Н	19.85		
		Eo	V	22.13		
		E2	Н	19.02		
		Н	V	22.44		
		П	Н	20.17		
	Llighoot	E1	V	22.22	22.00	Door
Highe	Highest	ET	Н	19.91	33.00	Pass
		FO	V	21.93		
		E2	Н	19.36		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP (dBm)	Limit (dBm)	Result
		Н	V	22.74		
		11	Н	20.73		
	1	Ε4	V	22.44	00.00	
	Lowest	E1	Н	20.11	33.00	Pass
		F0	V	21.72		
		E2	Н	18.90		
		Н	V	22.84		Pass
	Mistalla	П	Н	20.17	33.00	
LTE Band 2		E1	V	22.43		
(15MHz)	Middle		Н	20.01		
		E2	V	22.26		
			Н	19.17		
		ш	V	22.56		
		Н	Н	20.29		
	Llighaat	□ 4	V	22.35	22.00	Desa
	Highest	E1	Н	20.06	33.00	Pass
		F2	V	22.03		
		E2	Н	19.47		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP (dBm)	Limit (dBm)	Result
		Н	V	22.81		
		11	Н	20.80		
	1	Ε4	V	22.52	00.00	
	Lowest	E1	Н	20.19	33.00	Pass
		F0	V	21.82		
		E2	Н	19.00		
		Н	V	22.93		Pass
	N C - L - U -		Н	20.27	33.00	
LTE Band 2		E1	V	22.55		
(20MHz)	Middle		Н	20.14		
		ΓO	V	22.37		
		E2	Н	19.28		
		ш	V	22.64		
		Н	Н	20.39		
	Highoot	E 4	V	22.45	22.00	Door
	Highest	E1	Н	20.17	33.00	Pass
		E2	V	22.10		
			Н	19.56		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		1.1	V	22.75		
		Н	Н	20.74		_
		F4	V	22.44		
	Lowest	E1	Н	20.11	30.00	Pass
		Fo	V	21.73		
		E2	Н	18.91		
		Н	V	22.84		Pass
			Н	20.17	30.00	
LTE Band 4	Mistalla	E1	V	22.44		
(5MHz)	Middle		Н	20.02		
		F2	V	22.27		
		E2	Н	19.18		
		Н	V	22.56		
		П	Н	20.30		
	Himbook	E1	V	22.36	20.00	Door
High	Highest		Н	20.07	30.00	Pass
		E2	V	22.03		
			Н	19.48		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.63		
		11	Н	20.60		
	Laurant	E1	V	22.30	20.00	
	Lowest		Н	19.95	30.00	Pass
		F2	V	21.55		
		E2	Н	18.71		
		Н	V	22.68		Pass
		11	Н	19.97	30.00	
LTE Band 4	Middle	E1	V	22.22		
(10MHz)	Middle		Н	19.78		
		Eo	V	22.07		
		E2	Н	18.96		
		Н	V	22.40		
		П	Н	20.12		
	Highoot	E4	V	22.16	30.00	Daga
	Highest	E1	Н	19.86		Pass
		F0	V	21.89		
		E2	Н	19.32		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.59		
		11	Н	20.56		Pass
	1	- 4	V	22.25	00.00	
	Lowest	E1	Н	19.90	30.00	
		F2	V	21.49		
		E2	Н	18.65		
		Н	V	22.62		Pass
		11	Н	19.90	30.00	
LTE Band 4	M: al all a	E1	V	22.15		
(15MHz)	Middle		Н	19.70		
		Eo	V	22.00		
		E2	Н	18.89		
		Н	V	22.34		
		П	Н	20.06		
	Llighoot	E1	V	22.10	20.00	Door
	Highest	E1	Н	19.79	30.00	Pass
		Ε0	V	21.84		
		E2	Н	19.27		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	21.21		
		11	Н	18.74		
	Laurant	E1	V	21.54	20.00	
	Lowest		Н	18.50	30.00	Pass
		ΓO	V	20.97		
		E2	Н	18.01		
		Н	V	22.15		Pass
			Н	19.71	30.00	
LTE Band 4	M: al all a	E1	V	21.94		
(20MHz)	Middle		Н	19.47		
		Εĵ	V	21.48		
		E2	Н	18.25		
		Н	V	21.94		
		П	Н	19.87		
	Llighoot	E1	V	21.88	20.00	Door
	Highest	E1	Н	19.38	30.00	Pass
			V	21.36		
		E2	Н	18.76		



EUT mode	Channel	EUT Pol.	Antenna Pol.	ERP(dBm)	Limit (dBm)	Result
		Н	V	22.79		
		П	Н	20.78		
		F4	V	22.49	0.4.77	
	Lowest	E1	Н	20.16	34.77	Pass
		F0	V	21.79		
		E2	Н	18.97		
		Н	V	22.90		Pass
			Н	20.24	34.77	
LTE Band 12	N 42 - L - II -	E1	V	22.51		
(5MHz)	Middle		Н	20.09		
		F0	V	22.33		
		E2	Н	19.25		
		1.1	V	22.62		
		Н	Н	20.36		
	1.12 - 1 1	Ε4	V	22.42	0.4.77	Davis
Highe	Highest	E1	Н	20.13	34.77	Pass
		-	V	22.08		
		E2	Н	19.53		



EUT mode	Channel	EUT Pol.	Antenna Pol.	ERP(dBm)	Limit (dBm)	Result
		Н	V	22.73		
		11	Н	20.71		
		- 4	V	22.42	0.4.77	
	Lowest	E1	Н	20.08	34.77	Pass
		F0	V	21.70		
		E2	Н	18.87		
		Н	V	22.82		Pass
			Н	20.14	34.77	
LTE Band 12	N 42 - L - II -	E1	V	22.40		
(10MHz)	Middle		Н	19.98		
		Ε0.	V	22.23		
		E2	Н	19.14		
		1.1	V	22.53		
		Н	Н	20.27		
	I.P. b (Ε4	V	22.32	0.4.77	Davis
	Highest	E1	Н	20.03	34.77	Pass
			V	22.01		
		E2	Н	19.45		



16QAM mode:

EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.59		
		11	Н	20.56		
	Laurant	-	V	22.25	20.00	
	Lowest	E1	Н	19.90	30.00	Pass
		E2	V	21.50		
		E2	Н	18.65		
		Н	V	22.62		Pass
			Н	19.90	30.00	
LTE Band 2	Middle	E1	V	22.15		
(5MHz)	ivildale		Н	19.71		
		F0	V	22.01		
		E2	Н	18.89		
		Н	V	22.34		
		11	Н	20.06		
	Llighoot	E1	V	22.10	30.00	Door
	Highest	E1	Н	19.79		Pass
		F2	V	21.84		
		E2	Н	19.27		



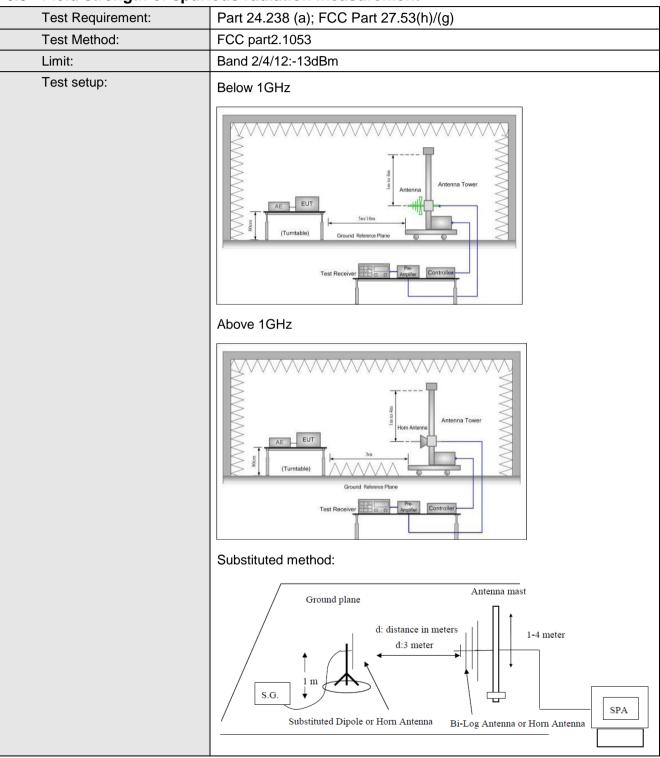
EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.73		
		11	Н	20.71		
	Laurant	E1	V	22.42	20.00	
	Lowest		Н	20.08	30.00	Pass
		F2	V	21.69		
		E2	Н	18.87		
		Н	V	22.81		Pass
			Н	20.13	30.00	
LTE Band 4	Middle	E1	V	22.40		
(5MHz)	Middle		Н	19.97		
		E2	V	22.23		
		E2	Н	19.14		
		Н	V	22.53		
		П	Н	20.27		
	Llighoot	E1	V	22.32	20.00	Door
F	Highest	E1	Н	20.02	30.00	Pass
		F.0	V	22.00		
		E2	Н	19.45		



EUT mode	Channel	EUT Pol.	Antenna Pol.	ERP(dBm)	Limit (dBm)	Result
		Н	V	22.77		
		Н	Н	20.76		
	1	- 4	V	22.47	0.4.77	D
	Lowest	E1	Н	20.14	34.77	Pass
		E2	V	21.76		
		E2	Н	18.94		
		Н	V	22.87	34.77	Pass
		- 11	Н	20.20		
LTE Band 12	NA: -I -II -	Middle E1	V	22.48		
(5MHz)	Middle		Н	20.06		
		E2	V	22.30		
			Н	19.21		
		Н	V	22.59		
		П	Н	20.33		
	Llighaat	E1	V	22.39	24.77	Pass
	Highest		Н	20.10	34.77	Pass
		E2	V	22.05		
		E2	Н	19.50		



6.9 Field strength of spurious radiation measurement





Test Procedure:	The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.
	2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations.
	3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method.
	4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency.
	ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) –
	Cable Loss (dB)
Test Instruments:	Refer to section 6.0 for details
Test mode:	Refer to section 6.1 for details
Test results:	Pass



Measurement Data

QPSK mode:

QPSK mode: Test mode:	LTE Band	d 2(5MHz)	Test channel:	Lowest
		Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3705.00	Vertical	-34.16		
5557.50	V	-36.51		
7410.00	V	-39.26	-13.00	Pass
9262.50	V	-42.37		
11115.00	V			
3705.00	Horizontal	-37.60		
5557.50	Н	-39.86		
7410.00	Н	-41.55	-13.00	Pass
9262.50	Н	-47.87		
11115.00	Н			
Test mode:	LTE Band	d 2(5MHz)	Test channel:	Middle
Fragues ov (MHz)	Spurious	Emission	Limit (dDm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3760.00	Vertical	-36.04		
5640.00	V	-37.25		
7520.00	V	-40.97	-13.00	Pass
9400.00	V	-43.65		
11280.00	V			
3760.00	Horizontal	-38.55		
5640.00	Н	-40.27		
7520.00	Н	-45.26	-13.00	Pass
9400.00	Н	-47.77		
11280.00	Н			
Test mode:	LTE Band	d 2(5MHz)	Test channel:	Highest
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (MHZ)	Polarization	Level (dBm)	Limit (ubin)	Kesuit
3815.00	Vertical	-33.96		
5722.50	V	-37.60		
7630.00	V	-40.44	-13.00	Pass
9537.50	V	-38.18		
11445.00	V			
3815.00	Horizontal	-36.83		
5722.50	Н	-39.34		
7630.00	Н	-45.05	-13.00	Pass
9537.50	Н	-48.80		
11445.00	Н			



Test mode:	LTE Band	2(10MHz)	Test channel:	Lowest
		Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3810.00	Vertical	-36.24		
5715.00	V	-38.81		
7620.00	V	-41.23	-13.00	Pass
9525.00	V	-43.50		
11430.00	V			
3810.00	Horizontal	-41.57		
5715.00	Н	-45.08		
7620.00	Н	-46.87	-13.00	Pass
9525.00	Н	-49.78		
11430.00	Н			
Test mode:	LTE Band	2(10MHz)	Test channel:	Middle
Fragues ov (MHz)	Spurious	Emission	Limit (dDm)	Dooult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3760.00	Vertical	-36.65		
5640.00	V	-39.43		
7520.00	V	-42.04	-13.00	Pass
9400.00	V	-44.46		
11280.00	V			
3760.00	Horizontal	-42.39		
5640.00	Н	-46.20		
7520.00	Н	-48.12	-13.00	Pass
9400.00	Н	-51.25		
11280.00	Н			
Test mode:	LTE Band	2(10MHz)	Test channel:	Highest
Fragues ov (MHz)	Spurious	Emission	Limit (dDm)	Dogult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3710.00	Vertical	-36.51		
5565.00	V	-39.42		
7420.00	V	-42.13	-13.00	Pass
9275.00	V	-44.67		
11130.00	V			
3710.00	Horizontal	-42.50		
5565.00	Н	-46.50	_	
7420.00	Н	-48.49	-13.00	Pass
9275.00	Н	-51.74	_	
11130.00	Н			



Test mode:	LTE Band	2(15MHz)	Test channel:	Lowest
		Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3805.00	Vertical	-33.63		
5707.50	V	-35.84		
7610.00	V	-37.99	-13.00	Pass
9512.50	V	-39.97		
11415.00	V			
3805.00	Horizontal	-38.29		
5707.50	Н	-41.32		
7610.00	Н	-42.90	-13.00	Pass
9512.50	Н	-45.46		
11415.00	Н			
Test mode:	LTE Band	2(15MHz)	Test channel:	Middle
Fraguera (MIII-)	Spurious	Emission	Lineit (dDne)	Daguit
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3760.00	Vertical	-32.71		
5640.00	V	-34.98		
7520.00	V	-37.18	-13.00	Pass
9400.00	V	-39.23		
11280.00	V			
3760.00	Horizontal	-37.50		
5640.00	Н	-40.61		
7520.00	Н	-42.24	-13.00	Pass
9400.00	Н	-44.85		
11280.00	Н			
Test mode:	LTE Band	2(15MHz)	Test channel:	Highest
Fragues av (MIII-)	Spurious	Emission	Lineit (dDne)	Daguit
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3715.00	Vertical	-34.25		
5572.50	V	-36.48		
7430.00	V	-38.65	-13.00	Pass
9287.50	V	-40.64		
11145.00	V			
3715.00	Horizontal	-38.95		
5572.50	Н	-42.00		
7430.00	Н	-43.60	-13.00	Pass
9287.50	Н	-46.17		
11145.00	Н			



Test mode:	LTE Band	2(20MHz)	Test channel:	Lowest
		Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3800.00	Vertical	-34.62		
5700.00	V	-36.51		
7600.00	V	-38.38	-13.00	Pass
9500.00	V	-40.09		
11400.00	V			
3800.00	Horizontal	-38.64		
5700.00	Н	-41.19		
7600.00	Н	-42.61	-13.00	Pass
9500.00	Н	-44.85		
11400.00	Н			
Test mode:	LTE Band	2(20MHz)	Test channel:	Middle
Fraguerov (MHz)	Spurious	Emission	Limit (dDm)	Dooult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3760.00	Vertical	-35.84		
5640.00	V	-37.98		
7520.00	V	-39.63	-13.00	Pass
9400.00	V	-41.55		
11280.00	V			
3760.00	Horizontal	-39.80		
5640.00	Н	-43.09		
7520.00	Н	-44.56	-13.00	Pass
9400.00	Н	-46.54		
11280.00	Н			
Test mode:	LTE Band	2(20MHz)	Test channel:	Highest
Fragues av (MIII-)	Spurious	Emission	Lineit (dDne)	Daguilt
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3720.00	Vertical	-33.18		
5580.00	V	-35.84		
7440.00	V	-37.92	-13.00	Pass
9300.00	V	-40.21		
11160.00	V			
3720.00	Horizontal	-38.10		
5580.00	Н	-42.12		
7440.00	Н	-43.91	-13.00	Pass
9300.00	Н	-46.42		
11160.00	Н			



Test mode:	LTE Ban	d 4(5MHz)	Test channel:	Lowest
F (5.41.1.)	Spurious Emission		11	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3425.00	Vertical	-34.24		
5137.50	V	-36.86		
6850.00	V	-38.89	-13.00	Pass
8562.50	V	-41.16		
10275.00	V			
3425.00	Horizontal	-39.09		
5137.50	Н	-43.04		
6850.00	Н	-44.79	-13.00	Pass
8562.50	Н	-47.23		
10275.00	Н			
Test mode:	LTE Ban	d 4(5MHz)	Test channel:	Middle
Erocuson ov (NALIE)	Spurious	Emission	Lineit (dDne)	Doorth
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3465.00	Vertical	-36.33		
5197.50	V	-38.45		
6930.00	V	-40.07	-13.00	Pass
8662.50	V	-41.98		
10395.00	V			
3465.00	Horizontal	-40.25		
5197.50	Н	-43.52		
6930.00	Н	-44.96	-13.00	Pass
8662.50	Н	-46.90		
10395.00	Н			
Test mode:	LTE Ban	d 4(5MHz)	Test channel:	Highest
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
1 requericy (IVII 12)	Polarization	Level (dBm)	Lillit (dbill)	Nesuit
3505.00	Vertical	-35.57		
5257.50	V	-37.49		
7010.00	V	-38.94	-13.00	Pass
8762.50	V	-40.67]	
10515.00	V			
3505.00	Horizontal	-39.08		
5257.50	Н	-42.06		
7010.00	Н	-43.40	-13.00	Pass
8762.50	Н	-45.15	_	
10515.00	Н			



Test mode:	LTE Band	I 4(10MHz)	Test channel:	Lowest
- (A411)	Spurious Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3430.00	Vertical	-34.09		
5145.00	V	-36.41		
6860.00	V	-38.20	-13.00	Pass
8575.00	V	-40.23		
10290.00	V			
3430.00	Horizontal	-38.37		
5145.00	Н	-41.90		
6860.00	Н	-43.48	-13.00	Pass
8575.00	Н	-45.63		
10290.00	Н			
Test mode:	LTE Band	I 4(10MHz)	Test channel:	Middle
Fragueray (MIII-)	Spurious	Emission	Limait (alDuna)	Daguit
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3465.00	Vertical	-32.58		
5197.50	V	-34.94		
6930.00	V	-36.76	-13.00	Pass
8662.50	V	-38.85		
10395.00	V			
3465.00	Horizontal	-36.95		
5197.50	Н	-40.55		
6930.00	Н	-42.15	-13.00	Pass
8662.50	Н	-44.34		
10395.00	Н			
Test mode:	LTE Band	I 4(10MHz)	Test channel:	Highest
Fraguency (MHz)	Spurious	Emission	Limit (dDm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Kesuit
3500.00	Vertical	-33.49		
5250.00	V	-35.79		
7000.00	V	-37.56	-13.00	Pass
8750.00	V	-39.59		
10500.00	V			
3500.00	Horizontal	-37.73		
5250.00	Н	-41.25		
7000.00	Н	-42.81	-13.00	Pass
8750.00	Н	-44.94		
10500.00	Н			



Test mode:	LTE Band	4(15MHz)	Test channel:	Lowest
		Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3435.00	Vertical	-37.18		
5152.50	V	-40.14		
6870.00	V	-42.44	-13.00	Pass
8587.50	V	-45.01		
10305.00	V			
3435.00	Horizontal	-42.69		
5152.50	Н	-47.13		
6870.00	Н	-49.06	-13.00	Pass
8587.50	Н	-51.83		
10305.00	Н			
Test mode:	LTE Band	4(15MHz)	Test channel:	Middle
Fraguera (MIII-)	Spurious	Emission	Lineit (dDne)	Daguit
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3465.00	Vertical	-37.48		
5197.50	V	-40.30		
6930.00	V	-42.48	-13.00	Pass
8662.50	V	-44.94		
10395.00	V			
3465.00	Horizontal	-42.72		
5197.50	Н	-46.96		
6930.00	Н	-48.82	-13.00	Pass
8662.50	Н	-51.46		
10395.00	Н			
Test mode:	LTE Band	4(15MHz)	Test channel:	Highest
Fragues av (MIII-)	Spurious	Emission	Lineit (dDne)	Daguilt
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3495.00	Vertical	-36.90		
5242.50	V	-39.52		
6990.00	V	-41.53	-13.00	Pass
8737.50	V	-43.83		
10485.00	V			
3495.00	Horizontal	-41.75		
5242.50	Н	-45.70		
6990.00	Н	-47.43	-13.00	Pass
8737.50	Н	-49.86	_	
10485.00	Н			



Test mode:	LTE Band	I 4(20MHz)	Test channel:	Lowest
	Spurious Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3440.00	Vertical	-33.47		
5160.00	V	-37.19		
6880.00	V	-39.80	-13.00	Pass
8600.00	V	-37.48		
10320.00	V			
3440.00	Horizontal	-36.05		
5160.00	Н	-38.96		
6880.00	Н	-44.65	-13.00	Pass
8600.00	Н	-48.12		
10320.00	Н			
Test mode:	LTE Band	I 4(20MHz)	Test channel:	Middle
Fragueray (MIII-)	Spurious	Emission	Lineit (dDne)	Decult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3465.00	Vertical	-35.57		
5197.50	V	-36.85		Pass
6930.00	V	-40.34	-13.00	
8662.50	V	-42.96		
10395.00	V			
3465.00	Horizontal	-37.79		
5197.50	Н	-39.91		
6930.00	Η	-44.87	-13.00	Pass
8662.50	Н	-47.10		
10395.00	Н			
Test mode:	LTE Band	I 4(20MHz)	Test channel:	Highest
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Trequency (IVITIZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Nesuit
3490.00	Vertical	-33.66		<u> </u>
5235.00	V	-36.08		
6980.00	V	-38.60	-13.00	Pass
8725.00	V	-41.65		
10470.00	V			
3490.00	Horizontal	-36.80		
5235.00	Н	-39.46		
6980.00	Н	-41.13	-13.00	Pass
8725.00	Н	-47.18	_	
10470.00	Н			

Remark

- 1. The emission behaviour belongs to narrowband spurious emission.
- 2. Remark"---" means that the emission level is too low to be measured
- 3. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Test mode:	LTE Band	l 12(5MHz)	Test channel:	Lowest
- (111)	Spurious Emission		Limit (ID)	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1403.00	Vertical	-36.92		
2104.50	V	-37.56		
2806.00	V	-38.81	-13.00	Pass
3507.50	V	-41.19		
4209.00	V			
1403.00	Horizontal	-39.83		
2104.50	Н	-41.65		
2806.00	Н	-42.82	-13.00	Pass
3507.50	Н	-45.53		
4209.00	Н			
Test mode:	LTE Band	12(5MHz)	Test channel:	Middle
(MII-)	Spurious	Emission	Limit (dDay)	Danult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1415.00	Vertical	-37.48		
2122.50	V	-39.55		
2830.00	V	-40.96	-13.00	Pass
3537.50	V	-45.20		
4245.00	V			
1415.00	Horizontal	-40.40		
2122.50	Н	-41.44		
2830.00	Н	-43.91	-13.00	Pass
3537.50	Η	-46.78		
4245.00	Н			
Test mode:	LTE Band	l 12(5MHz)	Test channel:	Highest
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (Minz)	Polarization	Level (dBm)	Limit (dbin)	Kesuit
1427.00	Vertical	-34.80		
2140.50	V	-36.20		
2854.00	V	-38.12	-13.00	Pass
3567.50	V	-39.34		
4281.00	V			
1427.00	Horizontal	-40.37		
2140.50	Н	-44.41		
2854.00	Н	-46.77	-13.00	Pass
3567.50	Н	-49.59		
4281.00	Н			

Remark:

- 1. The emission behaviour belongs to narrowband spurious emission.
- 2. Remark"---" means that the emission level is too low to be measured
- 3. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Test mode:	LTE Band	12(10MHz)	Test channel:	Lowest
Fig. (NALL)	Spurious Emission		Limeit (-ID)	Б
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1408.00	Vertical	-33.80		
2112.00	V	-36.13		
2816.00	V	-37.93	-13.00	Pass
3520.00	V	-39.97		
4224.00	V			
1408.00	Horizontal	-38.10		
2112.00	Н	-41.65		
2816.00	Н	-43.24	-13.00	Pass
3520.00	Н	-45.41		
4224.00	Н			
Test mode:	LTE Band	12(10MHz)	Test channel:	Middle
Frequency (MHz)	Spurious	Emission	Limit (dDm)	Result
Frequency (IVID2)	Polarization	Level (dBm)	Limit (dBm)	Result
1415.00	Vertical	-32.36		
2122.50	V	-34.73		
2830.00	V	-36.56	-13.00	Pass
3537.50	V	-38.66		
4245.00	V			
1415.00	Horizontal	-36.75		
2122.50	Н	-40.36		
2830.00	Н	-41.97	-13.00	Pass
3537.50	Н	-44.18		
4245.00	Н			
Test mode:	LTE Band	12(10MHz)	Test channel:	Highest
Fraguency (MU=)	Spurious	Emission	Limit (dDm)	Popult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1422.00	Vertical	-33.25		
2133.00	V	-35.56		
2844.00	V	-37.34	-13.00	Pass
3555.00	V	-39.37		
4266.00	V			
1422.00	Horizontal	-37.51		
2133.00	Н	-41.04		
2844.00	Н	-42.61	-13.00	Pass
3555.00	Н	-44.76		
4266.00	Н			

Remark:

- 1. The emission behaviour belongs to narrowband spurious emission.
- 2. Remark"---" means that the emission level is too low to be measured
- 3. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



16QAM mode:

Test mode:	LTE Band	d 2(5MHz)	Test channel:	Lowest	
- (111)	Spurious	Emission	11.14.15	D 11	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3705.00	Vertical	-32.05			
5557.50	V	-34.77		Pass	
7410.00	V	-36.94	-13.00		
9262.50	V	-39.07			
11115.00	V				
3705.00	Horizontal	-37.10			
5557.50	Н	-41.41			
7410.00	Н	-42.81	-13.00	Pass	
9262.50	Н	-45.73			
11115.00	Н				
Test mode:	LTE Band	d 2(5MHz)	Test channel:	Middle	
Fragues av (MIII-)	Spurious	Emission	Lineit (dDne)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)		
3760.00	Vertical	-35.34			
5640.00	V	-37.51		Pass	
7520.00	V	-39.22	-13.00		
9400.00	V	-40.96			
11280.00	V				
3760.00	Horizontal	-39.37			
5640.00	Н	-42.93		Pass	
7520.00	Н	-43.97	-13.00		
9400.00	Н	-46.32			
11280.00	Н				
Test mode:	LTE Band	d 2(5MHz)	Test channel:	Highest	
Frequency (MHz)	•	Emission	Limit (dBm)	Result	
1 ToqueTioy (IVIT12)	Polarization	Level (dBm)	Lillit (dDill)	Rosult	
3815.00	Vertical	-33.59			
5722.50	V	-35.60			
7630.00	V	-37.18	-13.00	Pass	
9537.50	V	-38.76			
11445.00	V				
3815.00	Horizontal	-37.28			
5722.50	Н	-40.61	_		
7630.00	Н	-41.59	-13.00	Pass	
9537.50	Н	-43.81			
11445.00	Н				

Remark:

- 4. The emission behaviour belongs to narrowband spurious emission.
- 5. Remark"---" means that the emission level is too low to be measured
- 6. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Test mode:	LTE Band	LTE Band 4(5MHz)		Lowest	
_	Spurious	Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3425.00	Vertical	-33.38			
5137.50	V	-36.04			
6850.00	V	-38.15	-13.00	Pass	
8562.50	V	-40.26			
10275.00	V				
3425.00	Horizontal	-38.33			
5137.50	Н	-42.57			
6850.00	Н	-43.90	-13.00	Pass	
8562.50	Н	-46.74			
10275.00	Н				
Test mode:	LTE Band	d 4(5MHz)	Test channel:	Middle	
(NALL_)	Spurious	Emission	Limit (dDas)	Danult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3465.00	Vertical	-35.95			
5197.50	V	-38.09			
6930.00	V	-39.77	-13.00	Pass	
8662.50	V	-41.51			
10395.00	V			1	
3465.00	Horizontal	-39.93			
5197.50	Н	-43.45		Pass	
6930.00	Н	-44.47	-13.00		
8662.50	Н	-46.78			
10395.00	Н				
Test mode:	LTE Band	d 4(5MHz)	Test channel:	Highest	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (IVITZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Result	
3505.00	Vertical	-34.79			
5257.50	V	-36.75			
7010.00	V	-38.28	-13.00	Pass	
8762.50	V	-39.84			
10515.00	V				
3505.00	Horizontal	-38.40			
5257.50	Н	-41.65]		
7010.00	Н	-42.58	-13.00	Pass	
8762.50	Н	-44.72]		
10515.00	Н				

Remark:

- 7. The emission behaviour belongs to narrowband spurious emission.
- 8. Remark"---" means that the emission level is too low to be measured
- 9. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Test mode:	LTE Band 12(5MHz)		Test channel:	Lowest	
- (2411)	Spurious	Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
1403.00	Vertical	-34.78			
2104.50	V	-35.52		Pass	
2806.00	V	-36.91	-13.00		
3507.50	V	-39.14			
4209.00	V				
1403.00	Horizontal	-37.88			
2104.50	Н	-40.07			
2806.00	Н	-40.88	-13.00	Pass	
3507.50	Н	-44.07			
4209.00	Н				
Test mode:	LTE Band	12(5MHz)	Test channel:	Middle	
Fragueray (MIII-)	Spurious	Emission	Lineit (dDne)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)		
1415.00	Vertical	-35.28			
2122.50	V	-37.44			
2830.00	V	-39.00	-13.00	Pass	
3537.50	V	-43.09			
4245.00	V			1	
1415.00	Horizontal	-38.39		Pass	
2122.50	Н	-39.79			
2830.00	Н	-41.92	-13.00		
3537.50	Н	-45.27			
4245.00	Н				
Test mode:	LTE Band	l 12(5MHz)	Test channel:	Highest	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
1 requericy (Wir 12)	Polarization	Level (dBm)	Lillit (dbill)	Nesuit	
1427.00	Vertical	-32.22			
2140.50	V	-33.73			
2854.00	V	-35.82	-13.00	Pass	
3567.50	V	-36.90			
4281.00	V				
1427.00	Horizontal	-38.01			
2140.50	Н	-42.44	_		
2854.00	Н	-44.47	-13.00	Pass	
3567.50	Н	-47.80			
4281.00	Н				

Remark:

- 1. The emission behaviour belongs to narrowband spurious emission.
- 2. Remark"---" means that the emission level is too low to be measured
- 3. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



6.10 Frequency stability V.S. Temperature measurement

Test Requirement:	FCC Part2.1055(a)(1)(b)
Test Method:	FCC Part2.1055(a)(1)(b)
Limit:	2.5ppm
Test setup:	Spectrum analyzer EUT Att. Variable Power Supply Note: Measurement setup for testing on Antenna connector
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to -20°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached.
Test Instruments:	Refer to section 6.0 for details
Test mode:	Refer to section 6.1 for details
Test results:	Pass



Measurement Data

QPSK mode:

QPSK mode: Reference	ce Frequency: LTE	Band 2 Middle c	nannel=18900 cł	nannel=1880MH	Z
Power supplied	T (20)	Frequer	ncy error	1.10.24 (0.000)	Result
(Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	
	-30	35	0.0186		
	-20	36	0.0191		
	-10	33	0.0176		
	0	29	0.0154		
12.0	10	32	0.0170	2.5	Pass
	20	30	0.0160		
	30	40	0.0213		
	40	37	0.0197		
	50	38	0.0202		
Referenc	e Frequency: LTE B	Band 4 Middle ch	annel=20175 ch	annel=1732.5MF	lz
Power supplied	Tomporature (%C)	Frequer	icy error	Limit (nnm)	Dogult
(Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	33	0.0190		Pass
	-20	32	0.0185	2.5	
	-10	31	0.0179		
	0	28	0.0162		
12.0	10	29	0.0167		
	20	28	0.0162		
	30	39	0.0225		
	40	34	0.0196		
	50	34	0.0196		
Referenc	e Frequency: LTE B	Band 12 Middle c	hannel=23095 c	hannel=707.5MF	lz
Power supplied (Vdc)	Temperature (°C)	Frequer	icy error		Result
rowei supplied (vac)	remperature (C)	Hz	ppm		Kesuit
	-30	56	0.0792		
	-20	62	0.0876		
12.0	-10	53	0.0749		
	0	46	0.0650		
	10	51	0.0721	2.5	Pass
	20	45	0.0636		
	30	75	0.1060		
	40	65	0.0919		
	50	63	0.0890		



16QAM mode:

16QAM mode:	ce Frequency: LTE	Band 2 Middle cl	hannel=18900 ch	annel=1880MH	Z
Power supplied	Frequency error			Lime't (co.	
(Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	33	0.0176		
	-20	34	0.0181		
	-10	31	0.0165		
	0	27	0.0144		
12.0	10	30	0.0160	2.5	Pass
	20	28	0.0149		
	30	38	0.0202		
	40	35	0.0186		
	50	36	0.0191		
Referenc	e Frequency: LTE E	Band 4 Middle ch	annel=20175 cha	annel=1732.5MF	lz
Power supplied	Temperature (°C)	Frequer	ncy error	Limit (ppm)	Result
(Vdc)	remperature (C)	Hz	ppm	Limit (ppm)	Result
	-30	26	0.0150	2.5	Pass
	-20	25	0.0144		
	-10	24	0.0139		
	0	22	0.0127		
12.0	10	23	0.0133		
	20	22	0.0127		
	30	29	0.0167		
	40	25	0.0144		
	50	27	0.0156		
Referenc	e Frequency: LTE E	Band 13 Middle c	hannel=23095 cl	nannel=707.5MH	łz
Power supplied (Vdc)	Temperature (°C)	Frequer	ncy error		Result
. сс. саррса (тас)	, ,	Hz	ppm		
	-30	54	0.0763		
	-20	59	0.0834		
	-10	51	0.0721		
	0	44	0.0622		
12.0	10	49	0.0693	2.5	Pass
	20	44	0.0622		
	30	72	0.1018		
	40	62	0.0876		
	50	61	0.0862		



6.11 Frequency stability V.S. Voltage measurement

Test Requirement:	FCC Part2.1055(d)(1)(2)
Test Method:	FCC Part2.1055(d)(1)(2)
Limit:	2.5ppm
Test setup:	Spectrum analyzer EUT Att. Variable Power Supply
	Note: Measurement setup for testing on Antenna connector
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency.
	3. Reduce the input voltage to specified extreme voltage variation (+/- 15%) and endpoint, record the maximum frequency change.
Test Instruments:	Refer to section 6.0 for details
Test mode:	Refer to section 6.1 for details
Test results:	Pass



Measurement Data

QPSK mode:

QPSK mode.						
Reference Frequency: LTE Band 2 Middle channel=18900 channel=1880MHz						
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result	
remperature (0)	(Vdc)	Hz	ppm	Енти (ррии)	Nesuit	
	13.20	19	0.0101			
25	12.00	19	0.0101	2.5	Pass	
	10.80	23	0.0122			
Reference Frequency: LTE Band 4 Middle channel=20175 channel=1732.5MHz						
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result	
remperature (C)	(Vdc)	Hz	ppm	Limit (ppm)	Nesuit	
	13.20	21	0.0121			
25	12.00	14	0.0081	2.5	Pass	
	10.80	19	0.0110	1		
Referenc	e Frequency: LTE E	Band 12 Middle c	hannel=23095 cl	nannel=707.5MF	łz	
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result	
remperature (C)	(Vdc)	Hz	ppm	- Limit (ppm)	Resuit	
	13.20	21	0.0297			
25	25 12.00	27	0.0382	2.5	Pass	
	10.80	29	0.0410			

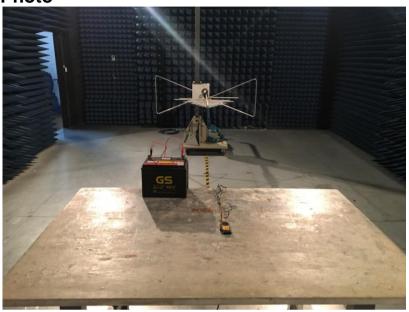


16QAM mode:

Reference Frequency: LTE Band 2 Middle channel=18900 channel=1880MHz							
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result		
remperature (C)	(Vdc)	Hz	ppm	- Limit (ppm)	Result		
	13.20	18	0.0096				
25	12.00	22	0.0117	2.5	Pass		
	10.80	24	0.0128				
Referenc	Reference Frequency: LTE Band 4 Middle channel=20175 channel=1732.5MHz						
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result		
remperature (C)	(Vdc)	Hz	ppm	- Limit (ppin)	Nesuit		
	13.20	22	0.0127				
25	12.00	16	0.0092	2.5	Pass		
	10.80	18	0.0104				
Referenc	e Frequency: LTE E	Band 13 Middle c	hannel=23095 ch	annel=707.5MF	łz		
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result		
remperature (C)	(Vdc)	Hz	ppm	Еши (ррш)	Nesuit		
	13.20	18	0.0254				
25	25 12.00	26	0.0367	2.5	Pass		
	10.80	27	0.0382				



7 Test Setup Photo





8 EUT Constructional Details

Reference to the test report No.: GTS201708000110F01

-----End-----